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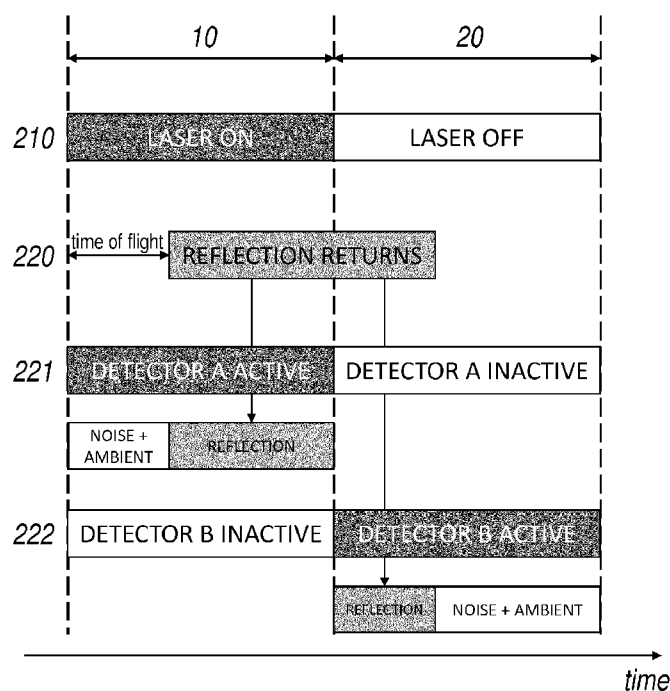


Fig. 3a

(57) **Abstract:** The present invention pertains to a system for determining a distance to an object comprising a solid-state light source, a detector comprising a plurality of picture elements, and processing means configured to calculate said distance to said object as a function of exposure values generated by picture elements in response to said detected light; wherein said picture elements generate exposure values by accumulating a first amount of electrical charge representative of reflected light during a first time window and a second electrical charge representative of reflected light during a second predetermined time window; wherein each picture element comprises two charge storage wells, said detecting occurring at said two charge storage wells; and wherein the system interleaves said predetermined time windows with time windows during which said picture elements are used in a function different from said detecting and/or said picture elements comprise at least one further charge storage well to perform said function different from said detecting of



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System and method for determining a distance to an object**Field of the Invention**

5 The present invention pertains to the field of systems for determining a distance to an object, in particular to time-of-flight based sensing systems based on active illumination to be used for the characterization of a scene or a part thereof, such as the surroundings of a vehicle.

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Background

In the field of remote sensing technology, mainly in the usage of making high-resolution maps of the surroundings, to be used in
15 many control and navigation applications such as but not limited to the automotive and industrial environment, gaming applications, and mapping applications, it is known to use time-of-flight based sensing to determine the distance of objects from a sensor. Time-of-flight based techniques include the use of RF modulated
20 sources, range gated imagers, or direct time-of-flight (DToF) imagers. For the use of RF modulated sources and range gated imagers, it is necessary to illuminate the entire scene of interest with a modulated or pulsed source. Direct time-of-flight systems, such as most LIDARs, mechanically scan the area of
25 interest with a pulsed beam, the reflection of which is sensed with a pulse detector.

In order to be able to correlate an emitted RF modulated signal with the detected reflected signal, the emitted signal must meet a
30 number of constraints. In practice, these constraints turn out to make the RF modulated systems highly impractical for use in vehicular systems: the attainable range of detection is very limited for signal intensities that are within conventional safety limits and within the power budget of regular vehicles.

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A direct TOF (DToF) imager, as used in most LIDAR systems, comprises a powerful pulsed laser (operating in a nanosecond pulse

regime), a mechanical scanning system to acquire from the 1D point measurement a 3D map, and a pulse detector. Systems of this type are presently available from vendors including Velodyne Lidar of Morgan Hill, California. The Velodyne HDL-64E, as an example of
5 state-of-the-art systems, uses 64 high-power lasers and 64 detectors (avalanche diodes) in a mechanically rotating structure at 5 to 15 rotations per second. The optical power required by these DToF LIDAR systems is too high to be obtained with semiconductor lasers, whose power is in the range of five to six
10 orders of magnitude lower. In addition, the use of mechanically rotating elements for scanning purposes limits the prospects for miniaturization, reliability, and cost reduction of this type of system.

15 United States Patent application publication no. 2015/0063387 in the name of Trilumina discloses a VCSEL delivering a total energy of 50 mW in a pulse having a pulse width of 20 ns. The commercially available Optek OPV310 VCSEL delivers a total energy of 60 mW in a pulse having a duration of 10 ns and it can be
20 estimated by extrapolation to have a maximum optical output power of 100 mW. This value is only realized under very stringent operating conditions, meaning optimal duty cycle and short pulse width so as to avoid instability due to thermal problems. Both the Trilumina disclosure and the Optek system illustrate that
25 continuous-wave VCSEL systems are reaching their physical limits with respect to optical peak power output, due to thermal constraints inherently linked to the VCSEL design. At these pulse energy levels, and using ns pulses as presently used in DToF applications, the mere number of photons that can be expected to
30 be usefully reflected by an object at a distance of 200 m is so low that it defeats detection by means of conventional semiconductor sensors such as CMOS or CCD or SPAD array. Thus, increasing the VCSEL power outputs by 5 or 6 orders of magnitude, as would be required to extend the range of the known DToF
35 systems, is physically impossible.

Even the use of avalanche diodes (AD or SPAD), which are theoretically sufficiently sensitive to capture the few returning photons, cannot be usefully deployed in the known LIDAR system architectures. A solid state implementation of an array of SPADs must be read out serially. A high number of SPADs is required to achieve the desired accuracy. The serial read-out constraints of the solid state implementation limits the bandwidth of the system turning it inappropriate for the desired accuracy. For accuracies such as that of the Velodyne system (0.02 m to 0.04 m, independent of distance), the required read-out data rate exceeds the practically achievable bandwidth in case of today's IC implementation. For operation at 120 m, a SPAD array of 500x500 pixels is required, which, in an IC-based implementation, must be read-out serially. For the same precision as the aforementioned Velodyne system, it would require 1000 pulses per millisecond and hence 1000 frames per millisecond, translating into a readout rate of 250 Gigapixels per second. This is believed to be technically unfeasible in the context of current SPAD IC technology.

The paper by Neil E. Newman et al., "High Peak Power VCSELs in Short Range LIDAR Applications", *Journal of Undergraduate Research in Physics*, 2013, <http://www.jurp.org/2013/12017EXR.pdf>, describes a VCSEL-based LIDAR application. The paper states that the maximum output power of the described prototype system was not great enough to do wide-field LIDAR at a range greater than 0.75 m. With a relatively focused beam (0.02 m spot size at 1 m distance), the authors were able to range a target object at a distance of up to 1 m.

The above examples clearly indicate that the optical power emitted by present semiconductor lasers cannot meet the power requirements necessary for operations in the known LIDAR systems to be of practical use in automotive applications (e.g. for ranges up to 200 m).

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United States patent no. 7,544,945 in the name of Avago Technologies General IP (Singapore) Pte. Ltd., discloses vehicle-

based LIDAR systems and methods using multiple lasers to provide more compact and cost-effective LIDAR functionality. Each laser in an array of lasers can be sequentially activated so that a corresponding optical element mounted with respect to the array of
5 lasers produces respective interrogation beams in substantially different directions. Light from these beams is reflected by objects in a vehicle's environment, and detected so as to provide information about the objects to vehicle operators and/or passengers. The patent provides a solid state projector in which
10 the individual lasers are consecutively activated in order to replace the known mechanical scanning in the known DToF LIDAR systems.

A high-accuracy medium-range surround sensing system for vehicles
15 that does not use time-of-flight detection, is known from international patent application publication WO 2015/004213 A1 in the name of the present applicant. In that publication, the localization of objects is based on the projection of pulsed radiation spots and the analysis of the displacement of detected
20 spots with reference to predetermined reference spot positions. More in particular, the system of the cited publication uses triangulation. However, the accuracy that can be achieved correlates with the triangulation base, which limits the further miniaturization that can be achieved.

25 US patent application publication no. US 2012/0038903 A1 discloses methods and systems for adaptively controlling the illumination of a scene. In particular, a scene is illuminated, and light reflected from the scene is detected. Information regarding levels
30 of light intensity received by different pixels of a multiple pixel detector, corresponding to different areas within a scene, and/or information regarding a range to an area within a scene, is received. That information is then used as a feedback signal to control levels of illumination within the scene. More
35 particularly, different areas of the scene can be provided with different levels of illumination in response to the feedback signal. US 2012/0038903 A1 does not disclose that the picture

elements are configured to generate exposure values by accumulating a first amount of electrical charge representative of a first amount of light reflected by the object during a first predetermined time window and a second electrical charge
5 representative of a second amount of light reflected by the object during a second predetermined time window, the second predetermined time window occurring after the first predetermined time window.

10 European patent application publication no. EP 2 322 953 A1 discloses a distance image sensor capable of enlarging the distance measurement range without reducing the distance resolution. A radiation source provides first to fifth pulse trains which are irradiated to the object as radiation pulses in
15 the first to fifth frames arranged in order on a time axis. In each of the frames, imaging times are prescribed at points of predetermined time from the start point of each frame, also the pulses are shifted respectively by shift amounts different from each other from the start point of the first to fifth frames. A
20 pixel array generates element image signals each of which has distance information of an object in distance ranges different from each other using imaging windows A and B in each of five frames. A processing unit generates an image signal by combining the element image signals. Since five times-of-flight measurement
25 are used, the width of the radiation pulse does not have to be increased to obtain distance information of the object in a wide distance range, and the distance resolution is not reduced. The solution presented by EP 2 322 953 A1 consists of measuring charges representative of the respective parts of the reflection
30 of a single pulse received in two consecutive time windows. As soon as a single reflected pulse has been received in the time windows A and B, the charges are transferred to the corresponding floating semiconductor areas for conversion into a "pixel image signal".

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European patent application publication no. EP 2 290 402 A1 discloses a range image sensor which is provided on a

semiconductor substrate with an imaging region composed of a plurality of two-dimensionally arranged units, thereby obtaining a range image on the basis of charge quantities output from the units. One of the units is provided with a charge generating region (region outside a transfer electrode) where charges are generated in response to incident light, at least two semiconductor regions which are arranged spatially apart to collect charges from the charge generating region, and a transfer electrode which is installed at each periphery of the semiconductor region, given a charge transfer signal different in phase, and surrounding the semiconductor region. EP 2 290 402 A1 is not intended to work with a pattern of spots of laser light. Moreover, the solution presented by EP 2 290 402 A1 does not disclose using a periodically repeated sequence of pulses.

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The article by Shoji Kawahito et al., "A CMOS Time-of-Flight Range Image Sensor With Gates-on-Field-Oxide Structure", *IEEE Sensors Journal*, Vol. 7, no. 12, p. 1578-1586, discloses a type of CMOS time-of-flight (TOS) range image sensor using single-layer gates on field oxide structure for photo conversion and charge transfer. This structure allows the realization of a dense TOF range imaging array with $15 \times 15 \mu\text{m}^2$ pixels in a standard CMOS process. Only an additional process step to create an n-type buried layer which is necessary for high-speed charge transfer is added to the fabrication process. The sensor operates based on time-delay dependent modulation of photocharge induced by back reflected infrared light pulses from an active illumination light source. To reduce the influence of background light, a small duty cycle light pulse is used and charge draining structures are included in the pixel. The TOF sensor chip fabricated measures a range resolution of 2.35 cm at 30 frames per second an improvement to 0.74 cm at three frames per second with a pulsewidth of 100 ns.

United States patent application publication no. US 2007/158770 A1 to Shoji Kawahito, discloses a range-finding image sensor based upon measurement of reflection time of light with reduced fabrication processes compared to standard CMOS manufacturing

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procedures. An oxide film is formed on a silicon substrate, and two photo-gate electrodes for charge-transfer are provided on the oxide film. Floating diffusion layers are used to convert charges to electronic potential, a mechanism traditionally inherited from the legacy technology of Charged Coupled Devices (CCD). Extra transistors are provided for resetting and a diffusion layer to provide a given reset voltage.

It is a disadvantage of the pixel disclosed in US 2007/158770 A1 that it uses non-standard technology and that the pixel design does not allow the addition of additional wells without sacrificing active surface area of the pixel. This is suboptimal for usage in sensor systems with ultra-low power lasers requiring large operational range. The used process is not commonly available in standard CMOS processes, which reduces this concept's applicability and its ability to be produced at an affordable cost in large volumes.

The range of a sensor based on such a design is also limited at the near end by saturation of the pixels by the strong reflections of projected light.

The saturation of pixels when sensing short-range reflections, or highly reflective objects such as traffic signs, license plates, etc., is especially problematic when the pixels are used in sensors for automotive applications, as is the purpose of the pixel according to the present invention, because Advanced Driver Assistance Systems (ADAS) and self-driving cars require high accuracy at short range. Moreover, in this application domain, accuracy at longer ranges, the ability to operate in bright ambient light conditions, and the requirement of compactness (requiring the use of solid-state semiconductor components) must not be sacrificed for the requirement of short-range accuracy.

United States patent application publication no. US 2013/0148102 A1 aims to address erroneous measurements caused by multiple reflections in the scene, which are due to the parallel

illumination and acquisition for all the pixels in today's state-of-the-art time-of-flight (TOF) range cameras. US 2013/0148102 A1 proposes to compensate for the multi-path fusing the results obtained by applying two spatially different illumination schemes, typically one to achieve highest possible lateral resolution and for the second one structuring the emitted light and by doing so lowering the lateral resolution but limiting the impact of multiple reflections. However, the system described in US 2013/0148102 A1 is a continuous-mode time-of-flight based sensor with global illumination, and the problems addressed in that document are inherent to global illumination. It is a disadvantage of global illumination schemes that they cannot realize the performance requirements of a semiconductor LIDAR when operating in range gating mode.

There is a continuing need to obtain extreme miniaturization and/or longer-range in complex vehicular surround sensing applications, such as ADAS (autonomous driving assistance system) applications and autonomous driving applications, and this at a reasonable cost and in a compact, semiconductor-integrated form factor, using technology apt for mass production.

Summary of the Invention

It is an objective of embodiments of the present invention to provide a further miniaturized and longer-range alternative for displacement-based vehicular surround sensing systems. Furthermore, it is an objective of embodiments of the present invention to provide a full solid-state alternative for the known LIDAR systems, in particular one wherein the semiconductor parts are apt for mass production.

According to an aspect of the present invention, there is provided a system for determining a distance to an object comprising: a solid-state light source arranged for projecting a pattern of discrete spots of laser light towards the object in a sequence of pulses; a detector comprising a plurality of picture elements, the

detector being configured for detecting light representing the pattern of discrete spots as reflected by the object in synchronization with said sequence of pulses; and processing means configured to calculate the distance to the object as a function of exposure values generated by said picture elements in response to said detected light; wherein the picture elements are configured to generate said exposure values by accumulating, for each pulse of said sequence, a first amount of electrical charge representative of a first amount of light reflected by said object during a first predetermined time window and a second electrical charge representative of a second amount of light reflected by said object during a second predetermined time window, said second predetermined time window occurring after said first predetermined time window; wherein each of the plurality of picture elements comprises at least two charge storage wells, and the detecting of the first amount of light and said detecting of the second amount of light occurs at respective ones of said at least two charge storage wells; and wherein each of the plurality of picture elements comprises at least one further charge storage well configured to perform a function different from the detecting of the first amount of light and the detecting of the second amount of light, said at least one further charge storage well having a charge storage capacity that is smaller than a charge storage capacity of said at least two charge storage wells.

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The solid-state semiconductor light source is preferably a semiconductor light source. The picture elements (pixels) of the detector are preferably CMOS picture elements. The detector is preferably provided with a narrowband filter.

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The term "charge storage well" designates a storage provided in the semiconductor substrate, e.g. a capacitor, that stores electrical charges generated by the conversion of photons impinging on the pixel.

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The present invention relies on the same physical principles as direct time-of-flight based ranging systems, viz. the fact that

light always takes a certain amount of time to travel a given distance. However, the present invention uses range gating to determine the distance travelled by a light pulse that has been transmitted and subsequently reflected by a target object.

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Automotive-grade sensors require small, cheap, and robust construction and accurate and reliable operation. Accordingly, there is a desire to construct such sensors with solid state technology, while avoiding any moving parts, preferable in semiconductor technology for mass producibility. A typical desired accuracy and reliability level can be quantified as an operating range of up to 200 m, a resolution of at least 1 million measurements per second, and an ability to operate correctly under outdoor ambient light conditions that may surpass an optical power density of 500 W/m² perpendicular while meeting applicable eye safe standards.

Although the use of solid state semiconductor technology implies relatively low-power lasers, which may result in a difference of 10⁶ in available light power (compared to the lasers used in traditional ToF LIDAR systems), the inventors have found that by judiciously adding a number of additional features, the challenges originating from the low power budget of the solid state projector can be solved.

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The present invention is *inter alia* based on the insight of the inventors that by judiciously combining range gating, an at least partially simultaneous spot pattern projection (based on a novel illumination scheme) and a low-power semiconductor light source, a substantially miniaturized, full solid state and energy-efficient distance detection method can be obtained, with a hitherto unattainable range. The term "pattern" as used herein refers to a spatial distribution of simultaneously projected spots. In order to determine the position of the detected spot reflection in three-dimensional space, it is necessary to combine the distance information obtained from the ranging step with angular information from each beam which is pre-calibrated to fix the

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remaining two spatial coordinates. A camera comprising a pixel array and suitably arranged optics can be used to provide the additional angular information, by identifying the pixel in which the reflection is detected.

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Embodiments of the present invention are based on the further insight of the inventors that in order to be able to use spot patterns generated by solid-state semiconductor light sources in a LIDAR system at the desired ranges, a way to circumvent the optical power limitations is needed. The inventors have found that by prolonging the pulse duration and by integrating the reflected energy of multiple VCSEL-generated light pulses within at least two semiconductor sensor wells, followed by a single read-out of the integrated charge, a solid-state LIDAR system can be obtained with a significantly greater operating range than is currently possible with solid-state implementations. Hereinafter, the term "storage" will be used to designate the well in which charge is accumulated in response to the detection of photons.

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It is an advantage of the present invention that the solid-state light source (the projector) and the solid-state sensor (in particular a CMOS sensor comprising an array of pixels, which is combined with adequate filters and optics to form an imager) may be integrated on the same semiconductor substrate. The solid-state light source may comprise a VCSEL array or a laser with a grating adapted to produce the desired pattern.

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Moreover, by assessing the reflected light energy detected in two consecutive time windows, and normalizing for the total accumulated charge in the two consecutive windows, the impact of varying reflectivity of the object under study and the contribution of ambient light can adequately be accounted for in the distance calculation algorithm.

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In the picture elements, charge representative of the impinging light can be accumulated at well level or at pixel level. An

advantage of charge accumulation at the well level is that read-out noise is minimized, leading to a better signal-to-noise ratio.

The transmission and detection of the sequence of pulses may be
5 repeated periodically.

The invention is further based on the insight of the inventors that in range-gating based imaging systems, it is advantageous to have a dual-well pixel (the presence of additional wells is not
10 excluded) whereby one of the charge storage wells has a substantially larger charge capacity than the other charge storage well. The term "well" may designate a single capacitance (electron capacity) produced in a semiconductor circuit by appropriate techniques, or a multitude of interconnected capacities acting
15 jointly as a single storage unit, arranged for example as a cascade. A pixel of this type is particularly useful where the physics of the situation in which the pixel is deployed lead to a predictable asymmetry in the amount of charge to be stored in the different wells, as is the case in a time-of-flight based
20 measuring system requiring high accuracy and a large distance range, resulting in a large photon span.

The inventors have further had the insight that different functions may also be performed by using at least one further
25 charge storage well provided in each picture element.

A third well may be provided to perform a variety of functions, provided that it is operated according to a timing scheme that takes into account the timing of the operation of the other wells.
30 In a distance sensing system in which the first well and the second well perform the basic range gating, the functions of the third well may include receiving the additional charges that are generated in response to photons arriving from a long-range highly reflective objects (such as a traffic sign or a license plate,
35 outside the time slots in which the first well and the second well are active), producing a regular 2-dimensional image of the scenery (outside the time slots in which the reflections of the

projected light arrive, optionally in synchronization with a wide-angle flash light for illuminating the scenery which may consist of a VCSEL array with a diffuser), or providing readings of the background light level that allow background light subtraction (by
5 subtracting from the charge levels accumulated in the first well and the second well, an amount of charge accumulated in the third well outside the time slots in which the reflections of the projected light arrive).

10 The third charge storage well may have a significantly smaller charge storage capacity than the first charge storage well and the second charge storage well, in particular if it is only used for capturing background light, as the background light arriving at the pixel array will typically have been strongly attenuated by
15 the ambient light reduction filters, in particular narrowband filters, that are preferably provided in a distance sensing system. If the third charge storage well is intended to be used for acquiring 2D images with additional lighting of the scenery (e.g., by means of a flash light) or for capturing reflections
20 from out-of-range highly reflective objects, it may be dimensioned to a similar storage capacity as the first or second charge storage well.

In an embodiment of the system according to the present invention,
25 said function comprises acquiring a two-dimensional image.

The 2D images acquired during the time windows that are not used for range gating or acquired by an additional well of the picture elements, may for example be combined with the distance
30 information derived from the exposure values obtained in the range gating frames in order to produce a 3D images.

In an embodiment of the system according to the present invention, said function comprises acquiring background light values.

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The background light values acquired during the time windows that are not used for range gating or acquired by an additional well of

the picture elements, may be subtracted from the exposure values obtained in the range gating frames in order to improve the accuracy of the calculated distance.

5 In an embodiment of the system according to the present invention, said function comprises accumulating, for all of the pulses of said sequence, a third amount of electrical charge representative of a third amount of light during a third predetermined time window.

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It is an advantage of this embodiment that reflections arriving after the second predetermined time window, e.g. reflections from highly-reflective objects situated outside the range covered by the first predetermined time window and the second predetermined
15 time window, can be captured. The corresponding charge can be used to calculate the distance of the out-of-range object.

In an embodiment of the system according to the present invention, the first charge storage well used for the detecting of the first
20 amount of light has a charge storage capacity that is greater than the second charge storage well used for the detecting of the second amount of light.

The inventors have found that to obtain a useful operating range
25 (between the lowest detectable light level and the light level at which saturation occurs), the second well may be dimensioned smaller than the first well, because the reflected amount of light that the second well will receive is always small: either the reflecting object is far away and the signal is strongly reduced
30 because of the distance, or the reflecting object is nearby and the bulk of the reflections arrives during the first time window.

In an embodiment, the system according to the present invention is further configured to perform the projecting and the detecting for
35 at least two consecutive sequences of pulses, each of the sequences being operated with a different duration of the first

predetermined time window and the second predetermined time window.

This embodiment relies on multiple consecutive measurements for
5 multiple sub-ranges of the desired total range. Each measurement
consists of a sequence of pulses emitted in respective first time
windows, during which the first charge storage well is activated,
followed by respective second time windows during which the second
charge storage well is activated, and optionally followed by
10 respective further time windows for performing different
functions. A sequence of pulses with its associated time windows
thus defines a measurement frame, the measurement range of which
is determined by the pulse width. By using different pulse widths
(and thus, a different duration of the first time window and the
15 second time window) from one measurement frame to the next,
different sub-ranges can be sensed. A pattern of frames may be
designed that combines to cover the entire desired target range.

In an embodiment of the system according to the present invention,
20 the first predetermined time window and the second predetermined
time window are of substantially equal duration and occur back-to-
back.

It is an advantage of this embodiment that the contribution of the
25 ambient light in the distance calculation formula can easily be
cancelled out by carrying out a subtraction of the accumulated
ambient light averaged from surrounding pixels.

In an embodiment, the system according to the invention is
30 configured to interleave the first and second predetermined time
windows with time windows during which said plurality of picture
elements are used in said function different from the detecting of
the first amount of light and the detecting of the second amount
of light.

To the extent that the pixel of the present invention resolves the short-range saturation problem, it removes the need for other work-arounds that extend the operating range at the short end. As the total range to be sensed is typically split into several subranges that can be spanned by individual frames having correspondingly selected pulse widths, the increase of the span of a measurement carried out in a single frame results in a decrease in the number of frames required to cover the entire desired range. The time that is freed up in this manner may be used to perform a different function; i.e. the frames that normally consist of the first predetermined time window and the second predetermined time window, may be extended with one or more further time windows for performing the different function (however, to ensure proper operation of the range gating function, no additional time windows should be inserted between the first predetermined time window and the second predetermined time window). The system may thus have a duty cycle (projector "on" time) of for example 25%, as resulting from a first time window (laser on, first charge storage well on), a second time window (laser off, second charge storage well on), a third time window (different function or idle time), and a fourth time window (different function or idle time), all time windows being of the same duration. A potential use of the third time window, occurring immediately after the first time window and the second time window, is to flush out any charge that may be generated by reflections of highly-reflective out-of-range objects, to avoid its adversely influencing the measurement of the reflections of the next projected pulse; a dedicated flush gate may be provided for this purpose.

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It is noted that these or other interleaved (non-ranging) time frames may also be used to perform functions that are independent of the aforementioned functions of the at least one further charge storage well (i.e., the third and any subsequent charge storage well).

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The reduction of the duty cycle also contributes to reducing the average amount of optical power emitted by the system, which improves the eye safety characteristics of the system. Further elements that determine the average amount of optical power emitted by the system include the emitted power per pulse, the number of pulses emitted per sequence, and the repetition rate of the sequences.

According to an aspect of the present invention, there is provided a vehicle, comprising: a system as described above arranged to operatively cover at least a part of an area surrounding said vehicle.

The system according to the present invention is particularly advantageous in a vehicle with an ADAS or autonomous driving control unit such as but not limited to an ECU (electronic control unit). The vehicle may further comprise a vehicle control unit, adapted for receiving measurement information from the system and for using the information for ADAS control or autonomous driving decision taking. The part of an area surrounding the vehicle may include a road surface ahead of, beside, or behind the vehicle. Accordingly, the system may provide road profile information of the surface ahead of the car, to be used for active suspension or semi-active suspension, and detection and tracking of objects around the vehicle for assisted driving, ADAS, and autonomous driving.

According to an aspect of the present invention, there is provided a camera, the camera comprising a system as described above, whereby the system is adapted to add 3D information to the camera image based on information obtained from the system, making it possible to create a 3D image.

The camera is adapted to acquire a 2D image in the known way. To this end, the camera may either comprise a dedicate sensor (pixel array), or it may use the sensor of the range-gating system according to the present invention. If the sensor of the range-

gating system is used, this may be done in various ways: e.g., at different points in time than the points in time at which the range gating takes place (e.g., in separate frames, optionally with the use of a flash light to illuminate the scenery, or in the same frames, but in different time windows); at the same time as the range gating, but excluding the pixels in which the reflections of the projected discrete spots are received. The range-gating sensor may be provided with a third well, in addition to the two wells used for range gating, for the purpose of acquiring the 2D image.

According to an aspect of the present invention, there is provided a method for determining a distance to an object, the method comprising: using a solid-state light source to project a pattern of discrete spots of laser light towards the object in a sequence of pulses; using a detector comprising a plurality of picture elements to detect light representing said pattern of discrete spots as reflected by the object in synchronization with said sequence of pulses; and calculating the distance to the object as a function of exposure values generated by said picture elements in response to said detected light; wherein the picture elements generate exposure values by accumulating, for each pulse of said sequence, a first amount of electrical charge representative of a first amount of light reflected by said object during a first predetermined time window and a second amount of electrical charge representative of a second amount of light reflected by said object during a second predetermined time window, said second predetermined time window occurring after said first predetermined time window; wherein each of the plurality of picture elements comprises at least two charge storage wells, and wherein the detecting of the first amount of light and the detecting of the second amount of light occurs at respective ones of the at least two charge storage wells; and wherein each of said plurality of picture elements comprises at least one further charge storage well configured to perform a function different from said detecting of said first amount of light and said detecting of said second amount of light, said at least one further charge storage

well having a charge storage capacity that is smaller than a charge storage capacity of said at least two charge storage wells.

In an embodiment of the method according to the present invention,
5 said function comprises acquiring a two-dimensional image.

In an embodiment of the method according to the present invention,
said function comprises acquiring background light values.

10 In an embodiment of the method according to the present invention,
said function comprises accumulating, for all of the pulses of
said sequence, a third amount of electrical charge representative
of a third amount of light during a third predetermined time
window.

15

In an embodiment of the method according to the present invention,
the first predetermined time window and the second predetermined
time window are of substantially equal duration and occur back-to-
back.

20

In an embodiment of the method according to the present invention,
each of the plurality of picture elements comprises at least two
charge storage wells, and wherein the detecting of the first
amount of light and the detecting of the second amount of light
25 occurs at respective ones of the at least two charge storage
wells.

In an embodiment of the method according to the present invention,
the projecting, the detecting, and the calculating are repeated
30 periodically.

In an embodiment of the method according to the present invention,
the first and second predetermined time windows are interleaved
with time frames during which the plurality of picture elements
35 are used in said function different from said detecting of said
first amount of light and said detecting of said second amount of
light.

According to an aspect of the present invention, there is provided a computer program product comprising code means configured to cause a processor to carry out the method described above.

5

The technical effects and advantages of embodiments of the camera, the vehicle, the method, and the computer program product, according to the present invention correspond, *mutatis mutandis*, to those of the corresponding embodiments of the system according to the present invention.

10

Brief Description of the Figures

These and other aspects and advantages of the present invention will now be described in more detail with reference to the accompanying drawings, in which:

15

Figure 1 represents a flow chart of an embodiment of the method according to the present invention;

20

Figure 2 schematically represents an embodiment of the system according to the present invention;

Figures 3a-3c represent a timing diagram for light projection and detection in embodiments of the present invention, to illustrate the operation of the two wells involved in range gating;

25

Figures 4a-4f represent timing diagrams for light projection and detection in embodiments of the present invention, to illustrate the operation of additional wells;

30

Figure 4g schematically illustrates how the individual frames in the sequence of Figure 3c, can be broken down into sequences with different timing parameters, each covering a portion of the targeted range;

35

Figure 5 provides diagrams of exemplary pixel output in function of incident light power as obtained by logarithmic tone mapping (top) and multilinear tone mapping (bottom);

5 Figure 6 provides a diagram of exemplary pixel outputs in function of incident light power as obtained by a high dynamic range multiple output pixel;

10 Figure 7 schematically represents a pixel for use in embodiments of the present invention;

15 Figure 8 schematically illustrates an embodiment of a pixel architecture with three charge wells (bins) with each a separate transfer gate for use in embodiments of the present invention;

Figure 9 schematically represents a pixel for use in embodiments the present invention, showing a first way of obtaining asymmetry of the wells;

20 Figure 10 schematically represents a pixel for use in embodiments of the present invention, showing a second way of obtaining asymmetry of the wells;

25 Figure 11 schematically illustrates a first exemplary optical arrangement for use in embodiments of the present invention;

Figure 12 schematically illustrates a second exemplary optical arrangement for use in embodiments of the present invention;

30 Figure 13 schematically illustrates a third exemplary optical arrangement for use in embodiments of the present invention; and

35 Figure 14 schematically illustrates a fourth exemplary optical arrangement.

Detailed Description of Embodiments

An ideal system for distance measurements in automotive applications, especially for advanced driver assistance (ADAS) and autonomous cars is a highly compact, mass-producible, low-cost solid-state LIDAR that can reliably detect objects up to 200
5 meter. Optimal size and cost reduction can only be reached if the sensor is "true solid state", not only in the sense that it lacks moving parts, but that the components can be mass-produced by semiconductor technology (Moore's law). There are two competing requirements that must be reconciled in order to achieve the above
10 stated goal: the optical output power must exceed the power of the ambient light that illuminates the objects at the furthest distance (with a power of up to 500 W/m^2), but at the same time it must stay below the maximum power imposed by the stringent (class 1/M) eye safety norms.

15

The system according to the present invention reconciles this apparently conflicting requirements by providing a LIDAR with parallel spot-pattern illumination of the scene using a large array of lasers. It is advantageous to use VCSEL arrays for this
20 purpose because they have a good beam quality (m2 factor) so that the beams can be focused in very small, discrete spots (to exceed the strong daylight) and they can be mass-produced by semiconductor technology.

25 To date, semiconductor-based light sources such as VCSEL arrays have not been used in LIDAR systems with parallel illumination, because of the extremely low optical power on each individual VCSEL, of the order of 10 mW. In order to reach the energy of 0.1 μJ that is needed for sufficient precision, the distance
30 measurement must be extended to $0.1 \mu\text{J}/10 \text{ mW} = 10 \mu\text{sec}$.

In the range-gating method (an indirect time-of-flight method), used in the present invention, the pulse duration must be of the order of the time that the light takes to reach the object and to
35 return (in view of the target range of 200 m, this adds up to a round-trip of 400 m) which is of the order of 1 μs . Thus in order to gain sufficient precision, the signal must be accumulated over

at least 10, and preferably up to 100 (or more, to improve precision), successive pulses. However, the accumulation of so many individual measurements that each result in only a few electrons, tends to drown the desired signal in read-out noise.

5 The inventors have overcome this challenge by developing a low-noise CMOS detector in which the accumulation of the signals is done on capacitors and only read out after accumulation.

The resulting total duration of the measurement of 100 μ s is still very well below the required time resolution to detect moving
10 objects.

Combining the minimal optical pulse energy for an individual measurement of 0.1 μ J with the class 1/M eye safety norm of 1 mJ (averaged over 1 second) leads to the conclusion that the eye-
15 safety norm limits the number of distance measurements (assuming a distance up to 200 m and in an angular range of 30° x 30°) to 1 million measurements per second.

The surround sensing systems of the type disclosed in
20 international patent application publication WO 2015/004213 A1, in the name of the present applicant, has the advantage of observing an extensive scene while illuminating that scene simultaneously or partially simultaneously only in a number of discrete and well-defined spots, in particular a predefined spot pattern. By using
25 VCSEL lasers with an outstanding bundle quality and a very narrow output spectrum, it is possible to obtain a detection range with a limited amount of output power, even in the presence of daylight. The actual ranging performed in the system of WO 2015/004213 A1 relies on displacement detection, in particular triangulation,
30 which was understood to be the only method practically available in the context of the long (quasi-stationary) pulse durations that were necessary in view of the power budget. To date, it had not been possible to achieve the same power/performance characteristics with a compact, semiconductor based time-of-flight
35 based system.

The present invention overcomes this limitation by radically changing the way the time-of-flight based system operates. The invention increases the total amount of light energy emitted for each time-of-flight measurement (and thus, the number of photons available for detection at the detector for each time-of-flight measurement) by increasing the duration of individual pulses and by producing a virtual "composite pulse", consisting of a sequence of a large number of individual pulses. This bundling of extended pulses allowed the inventors to obtain the required amount of light energy (photons) for the desired operational range with low-power VCSELs. Preferably, the VCSEL lasers have an outstanding bundle quality and a very narrow output spectrum, so as to obtain a long detection range with a limited amount of output power, even in the presence of daylight. Preferably, the VCSEL lasers are thermally stabilized to ensure consistent operational characteristics.

Where an individual pulse of pre-existing LIDAR systems may have a duration of 1 ns, the systems according to the present invention benefit from a substantially longer pulse duration to partially compensate for the relatively low power level of semiconductor lasers such as VCSELs; in embodiments of the present invention, individual pulses within a sequence may have an exemplary duration of 1 μ s (this is one possible value, chosen here to keep the description clear and simple; more generally, in embodiments of the present invention, the pulse duration may for example be 500 ns or more, preferably 750 ns or more, most preferably 900 ns or more). In an exemplary system according to the present invention, a sequence may consist of 1000 pulse cycles, thus adding up to a duration of 1 ms. Given the fact that light would need approximately 0.66 μ s to travel to a target at a distance of 100 m and back to the detector, it is possible to use composite pulses of this duration for ranging at distance of this order of magnitude; the skilled person will be able to adjust the required number of pulse cycles in function of the selected pulse width and the desired range. The detection of the sequence preferably comprises detecting the individual pulses in synchronization with

the VCSEL-based light source, and accumulating the charges generated in response to the incoming photons at the pixel well level for the entire sequence prior to read-out. The term "exposure value" is used hereinafter to designate the value
5 representative of the charge (and thus of the amount of light received at the pixel) integrated over the sequence. The sequence emission and detection may be repeated periodically.

The present invention operates by using range gating. Range gated
10 imagers integrate the detected power of the reflection of the emitted pulse for the duration of the pulse. The amount of temporal overlap between the pulse emission window and the arrival of the reflected pulse depends on the return time of the light pulse, and thus on the distance travelled by the pulse. Thus, the
15 integrated power is correlated to the distance travelled by the pulse. The present invention uses the principle of range gating, as applied to the sequences of pulses described hereinabove. In the following description, the integration of individual pulses of a sequence at the level of a picture element to obtain a
20 measurement of the entire sequence is implicitly understood.

The picture elements (pixels) in the CMOS sensor are preferably based on pinned diodes and transfer gate technology to ensure a complete transfer of the accumulated photocharges upon read-out,
25 so as to maximize the accuracy, and to be compliant with deep micron CMOS fabrication technology, apt for mass producing in standard CMOS foundries.

Figure 1 represents a flow chart of an embodiment of the method
30 according to the present invention. Without loss of generality, the ranging method is described with reference to a range gating algorithm. In a first time window **10**, the method comprises projecting **110** a pattern of spots of laser light (e.g. a regular or an irregular spatial pattern of spots) from a light source
35 comprising a solid-state light source **210** onto any objects in the targeted area of the scenery. The spatial pattern is repeatedly projected in a sequence of pulses.

As indicated above, the solid-state light source may comprise a VCSEL array or a laser with a grating adapted to produce the desired pattern. In order for the system to operate optimally, even at long ranges and with high levels of ambient light (e.g., in daylight), a VCSEL for use in embodiments of the present invention is preferably arranged to emit a maximum optical power per spot per unit of area. Thus, lasers with a good beam quality (low M2-factor) are preferred. More preferably, the lasers should have a minimal wavelength spread; a particularly low wavelength spread can be achieved with monomode lasers. Thus, substantially identical can reproducibly be generated, with the necessary spatial and temporal accuracy.

During the same time window in which a pulse is emitted, or in a substantially overlapping time window, a first amount of light representing the pattern of spots as reflected by the object of interest is detected **120** at a detector, which is preferably arranged as near as possible to the light source. The synchronicity or near synchronicity between the projection **110** of the spot pattern and the first detection **120** of its reflection, is illustrated in the flow chart by the side-by-side arrangement of these steps. In a subsequent second predetermined time window **20**, a second amount of light representing the reflected light spot is detected **130** at the detector. During this second window **20**, the solid-state light source is inactive. The distance to the object can then be calculated **140** as a function of the first amount of reflected light and the second amount of reflected light.

The first predetermined time window **10** and the second predetermined time window **20** are preferably back-to-back windows of substantially equal duration, to facilitate noise and ambient light cancellation by subtracting one of the detected amounts from the other one. An exemplary timing scheme will be described in more detail below in conjunction with Figure 3.

The detector comprises a plurality of picture elements, i.e. it consists of a picture element array with adequate optics arranged to project an image of the scenery (including the illuminated spots) onto the picture element. The term "picture element" as
5 used herein may refer to an individual light-sensitive area or well of a pixel, or to an entire pixel (which may comprise multiple wells, see below). For every given projected spot, the detecting **120** of the first amount of light and the detecting **130** of the second amount of light occurs at the same one or the same
10 group of the plurality of picture elements.

Without loss of generality, each of the picture elements may be a pixel comprising at least two charge storage wells **221, 222**, such that the detecting **120** of the first amount of light and the
15 detecting **130** of the second amount of light can occur at the respective charge storage wells **221, 222** of the same pixel or pixel group.

Figure 2 schematically represents an embodiment of the system
20 according to the present invention, in relation to an object **99** in the scenery of interest. The system **200** comprises a solid-state light source **210** for projecting a pattern of a sequence of spots, which may be repeated periodically, onto the object **99**. A detector **220** is arranged near the light source and configured to detect
25 light reflected by the object.

The light beam bouncing off the object **99** is illustrated as an arrow in dashed lines, travelling from the light source **210** to the object **99** and back to the detector **220**. It should be noted that
30 this representation is strictly schematic, and not intended to be indicative of any actual relative distances or angles.

A synchronization means **230**, which may include a conventional clock circuit or oscillator, is configured to operate the solid-
35 state light source **210** so as to project the pattern of spots onto the object during first predetermined time windows **10** and to operate the detector **220** so as to detect a first amount of light

representing the light spot(s) reflected by the object **99** at substantially the same time. It further operates the detector **220** to detect a second amount of light representing the light spots reflected by the object **99**, during respective subsequent second
5 predetermined time windows **20**. Appropriate processing means **240** are configured to calculate the distance to the object as a function of the first amount of reflected light and the second amount of reflected light.

10 Figure 3 represents a timing diagram for light projection and detection in embodiments of the present invention. For clarity reasons, only a single pulse of the pulse sequence which is repeated periodically of Figure 1 is illustrated, which consists of a first time window **10** and a second time window **20**.

15

As can be seen in Figure 3a, during the first time window **10**, the solid-state light source **210** is in its "ON" state, emitting the pattern of light spots onto the scenery. During the second time window **20**, the solid-state light source **210** is in its "OFF" state.

20

The arrival of the reflected light at the detector **220** is delayed relative to the start of the projection by an amount of time that is proportional to the distance travelled (approximately 3.3 ns/m in free space). Due to this delay, only a part of the reflected
25 light will be detected at the first well **221** of the detector **220**, which is only activated during the first time window **10**. Thus, the charge accumulated in this first well during its period of activation (the first time window **10**) consists of a part representing only the noise and the ambient light impinging on the
30 pixel prior to the arrival of the reflected pulse, and a part representing the noise, the ambient light, and the leading edge of the reflected pulse.

The latter part of the reflected pulse will be detected at the
35 second well **222** of the detector **220**, which is only activated during the second time window **20**, which preferably immediately follows the first time window **10**. Thus, the charge accumulated in

this second well during its period of activation (the second time window **20**) consists of a part representing the noise, the ambient light, and the trailing edge of the reflected pulse, and a part representing only the noise and the ambient light impinging on the pixel after the arrival of the reflected pulse.

The greater the distance between the reflecting object **99** and the system **200**, the smaller the proportion of the pulse that will be detected in the first well **221** and the larger the proportion of the pulse that will be detected in the second well **222**.

If the leading edge of the reflected pulse arrives after the closing of the first well **221** (i.e., after the end of the first time window **10**), the proportion of the reflected pulse that can be detected in the second well **222** will decrease again with increasing time of flight delay.

The resulting amounts of charge **A**, **B** in each of the respective wells **221**, **222** for varying distances of the object **99** is shown in Figure 3b. To simplify the representation, the effect of the attenuation of light with distance, according to the inverse square law, has not been taken into account in the diagram. It is clear that for time of flight delays up to the combined duration of the first time window **10** and the second time window **20**, the time of flight delay can in principle unambiguously be derived from the values of **A** and **B**:

- For time of flight delays up to the duration of the first time window **10**, **B** is proportional to the distance of the object **99**. To easily arrive at a determination of the absolute distance, the normalized value $B/(B+A)$ may be used, removing any impact of non-perfect reflectivity of the detected object and of the inverse square law.
- For time of flight delays exceeding the duration of the first time window **10**, **A** consists of daylight and noise contributions only (not illustrated), and **C-B** is substantially proportional (after correcting for the inverse

square law) to the distance of the object **99**, where **C** is an offset value.

While Figures 3a and 3b illustrate the principle of the invention
5 in relation to a single pulse emitted in the time window **10**, it shall be understood that the illustrated pulse is part of a sequence of pulses as defined above. Figure 3c schematically illustrates exemplary timing characteristics of such a sequence. As illustrated, the illumination scheme **40** consists of a repeated
10 emission of a sequence **30** of individual pulses **10**. The width of the individual pulses **10** is determined by the maximal operating range. The entire sequence may be repeated at a frequency of, for example, 60 Hz.

15 The inventors have found that in systems such as described herein, reflections of light by objects at a short distances are more likely to cause pixel saturation, because the attenuation of such a reflection will be much less than that of a reflection originating from a more distant object (due to the inverse-square
20 law of light attenuation over distance). As certain applications, such as automotive applications, require accurate system operation up to relatively long distances, a large photon span must be covered between the nearest distances of operation and the farthest distances of operation. With these constraints, pixel
25 saturation at short range is a very real risk, in particular at the first well (which receives the bulk of the reflection at short range). The inventors have found that for given total pixel space, the saturation problem can be mitigated by using an asymmetric well arrangement, in which the photon capacity represented by the
30 first well is increased, and the photon capacity represented by the second well is decreased. If the increase and decrease are balanced, an increase of the dynamic range can be obtained at no additional pixel surface cost.

35 The pixel may further comprise circuitry allowing the pixel to switch between a charging mode and a discharging mode. In the charging mode, light impinging on said pixel causes the first

charge storage well or the second charge storage well (according to the present stage of the illumination scheme) to increase a stored amount of charge. In the discharging mode, preferably activated after the charging mode for an equal amount of time, light impinging on said pixel causes said first charge storage well or said second charge storage well to decrease the stored amount of charge. This switching scheme allows an amount of charge corresponding to the background light to be removed from the charge storage wells.

Embodiments of the present invention may employ correlated double sampling to correct the samples for the thermal noise related to the capacity of the wells (also designated as "kTC noise"). To this end, the electronics of the pixel may be designed to carry out a differential measurement between the reset voltage (V_{reset}) and the signal voltage (V_{signal}), for example by measuring V_{reset} at the beginning of the frame and measuring V_{signal} at the end of the frame. As an alternative to an electronic (in-pixel) implementation, correlated double sampling may also be implemented by digitally subtracting the read-out signals ($V_{\text{signal}} - V_{\text{reset}}$) in a processor.

To increase the amount of light that reaches the photosensitive elements (in particular diodes) in the pixel structure, embodiments of the present invention may use backside illumination; in that case, the pixel circuitry is behind the photosensitive layer, thus reducing the number of layers that must be traversed by the impinging photons to read the photosensitive elements.

The ranging system according to the present invention may be integrated with a triangulation-based system in accordance with WO 2015/004213 A1. If miniaturization is aimed for, the triangulation-based system will end up having a relatively small distance between its projector and its detector, thus leaving it with a reduced operating range. However, it is precisely at short range that the combination presents its benefit, because the

triangulation-based system can cover the distances at which the time-of-flight based system cannot operate sufficiently accurately.

5 The entire ranging process may be repeated iteratively, so as to monitor the distance to the detected object or objects over time. Thus, the result of this method can be used in processes that require information about the distance to detected objects on a continuous basis, such as object detection and tracking, assisted
10 driving, advanced driver assistance systems, vehicles with an active suspension, or autonomous vehicles. An iteratively repeated range gating sequence is schematically represented in the timing diagram of Figure 4a, in which each frame corresponds of a sequence of pulses of the projector (P) (the timing of the pulses is indicated by the lowercase 'p'), which is synchronized to
15 activations of the imager (I) (the accumulation of charges in the first well is indicated by the lowercase 'a', while the accumulation of charges in the second well is indicated by the lowercase 'b'). Without loss of generality, only two consecutive
20 frames are illustrated.

Figure 4b represents a modified timing scheme, containing two additional time slots for every projection pulse. These additional time slots are used to discharge the respective wells at a rate
25 proportional to the intensity of the light impinging on the pixel when no reflection of the projected light is received. As the light received in the absence of a pulse represents the background light, with only a tiny time offset relative to the point in time at which the pulse reflection is received, this scheme effectively
30 removes the background light component from the charge accumulated in the first well and the second well, for each projector pulse.

In order to implement the above mentioned discharging phase, the pixel may comprise a capacitor for storing the charge, coupled to
35 the photodiode by appropriate transfer gates. The accumulating phase then comprises transferring charges to a first side of the

capacitor, and the decreasing comprises transferring charges to the second side of the capacitor.

The system according to the present invention preferably comprises
5 additional wells and transfer gates.

Figure 4c represents a modified timing scheme, containing one additional time slot for every projection pulse. This additional time slot is used to accumulate photocharges in a third well (the
10 accumulation of charges in the third well is indicated by the lowercase 'c'). As the light received in the third well arrives in the absence of a pulse, it represents the background light, with only a tiny time offset relative to the point in time at which the pulse reflection is received. The charge accumulated in the third
15 well may therefore be subtracted from the charges in the first well and the second well to effectively remove the background light component from the latter charges.

Figure 4d represents a variant of the timing scheme of Figure 4c,
20 in which the third well is activated during a number of time slots after the completion of the same number of projector pulses. As the light thus received in the third well arrives in the absence of a pulse, it represents the background light, with only a slightly larger time offset relative to the points in time at
25 which the pulse reflection is received. The charge accumulated in the third well may therefore be subtracted from the charges in the first well and the second well to effectively remove the background light component from the latter charges.

30 Figure 4e represents yet another variant of the timing scheme of Figure 4c, in which the first well is activated in a separate frame, after the completion of a frame in which the projector and the first and second well are active for range gating. As the light thus received in the first well arrives in the absence of a
35 pulse, it represents the background light, with again a slightly larger time offset relative to the points in time at which the pulse reflection is received. The charge accumulated in the first

well in the separate frame may therefore be subtracted from the charges in the first well and the second well to effectively remove the background light component from the latter charges.

5 The combination of the large desired operational range (in the order of 200 m) and the high desired accuracy (correctly detect as few as 1000 photons at the furthest point) results in a huge span between the largest number of photons that may be received in one well in one frame (in the case of reflections at short range), and
10 the lowest number that may be received in one well in one frame.

Figure 4f represents a modified timing scheme, which differs from the scheme of Figure 4a in that the duration of a single time slot varies from one slot to the next. In this way, the detection
15 threshold and the saturation point for different frames will occur at different distances, and the information obtained from a number of consecutive frames may be combined to obtain accurate distance measurements for both nearby objects and far-away objects.

20 Figure 4g schematically illustrates how the individual frames in the sequence of Figure 3c, which may fail to cover the entire targeted range of distances $[Z_{\min}, Z_{\max}]$ as a result of the constraints imposed by N_{\max} (maximal number of electrons that can be stored without saturating the pixel) and N_{\min} (minimum number of
25 pixels required for accurate read-out), can be broken down into sequences with different timing parameters, each covering a portion of the targeted range $[z_{\min}(i), z_{\max}(i)]$ that can more easily be covered within the same constraints on the number of photons.

30

With reference to the symbols introduced above and used in Figure 4g, the corresponding electron amounts $n_{\min}(i)$ and $n_{\max}(i)$ of the subranges are defined by:

- The maximum allowable number of electrons (using "FPC" for
35 the full pixel capacity, which corresponds to full well capacity in case there are no additional capacities):

$$n_{\max} = N_{\min} \times \left(\frac{z(i)}{z(i+1)} \right) \leq \text{FPC}, \text{ with } z(0) = Z_{\max}$$

- The minimum required accuracy level: $n_{min} = N_{min}$
- $z_{max}(i) = z_{min}(i-1)$

Additionally, the pulse characteristics can be determined as follows:

- 5 - the pulsewidth $\tau(i) = \frac{z_{max}(i)}{c}$
- the total "on" time is reduced proportionally to $\frac{N_{max}}{N_{min}}$ to respect the limits imposed by the full pixel capacity and the accuracy level.

10 The above principles may be further clarified by the following non-limiting numerical example.

15 A Lambertian reflecting surface with 10% reflectivity at a distance of 150m must provide 1000 electrons to obtain an accuracy of 1,6%. At the same distance, a 100% reflecting surface will generate 10000 electrons. With a full well capacity of 200000 electrons, the following multi-frame solution is proposed:

	Sub-range	Pulse Width	Total "on" time
Frame 1	150m - 33m	1 μ s	1 ms
Frame 2	7.4m - 33m	22 ns	50 μ s
Frame 3	1.65m - 7.4m	4.9 ns	2.5 μ s
Frame 4	0.37m - 1.65m	1.1 ns	0.125 μ s

20 It should be noted that for robustness reasons, it may be advantageous to provide an overlap in the subranges.

25 For assuring the same 3D resolution, it may be advantageous to use a faster camera: e.g., a camera operating at 180Hz with 3-frame interleaving gives the same data speed as a 60Hz with single frame operation.

Depending on the mode in which a system according to the present invention is used (as exemplified in Figures 7a-7g), the duty cycle will vary. It can easily be seen that when some frames are

used for capturing out-of-range reflections or acquiring a 2D image, a smaller fraction of time is available for the actual ranging. It is an advantage of the use of three-well or four-well pixel according to the present invention that several functions
5 can be performed simultaneously, thus increasing the duty cycle of the range-gating function.

Blooming is a phenomenon that happens when the charge in a pixel exceeds the saturation level of that specific pixel (as in the
10 case of short-range reflections or reflections from highly reflective surfaces such as traffic signs or license plates). Consequently, the charge starts to overflow and causes nuisance in adjacent pixels. This creates inaccurate data in the neighboring pixels.

15 Preferably, the pixels of the system according to the present invention are provided with anti-blooming electronics, which may in particular include the aforementioned third well or even a fourth well, to bleed off the excess charge before it saturates
20 the relevant well and spills over to the wells of adjacent pixels. In particular when the information from neighboring spots is used for the elimination of background light, it is of great importance to have an accurate estimation of the background light which is obtained independently (and without contamination) from
25 neighboring pixels. Likewise, when the pixels that do not receive spot reflections are used to simultaneously generate a regular 2D image, it is highly desirable that pixels adjacent to pixels receiving a spot reflection are not affected by charge spills from the latter pixels.

30 An anti-blooming arrangement as described above may also contribute to increasing the range of the system at the near end. At short distances, pixels receiving the main portion of a reflected spot are prone to saturation. By applying an anti-
35 blooming arrangement, a spill-over of charges from such saturated pixels to neighboring pixels is avoided. Hence, neighboring pixels can continue to operate normally. As the area illuminated by a

reflected spot will typically cover more than just one pixel, some of the neighboring pixels may be expected to receive a portion of the reflected spot that is sufficiently small to avoid saturation, yet usable to perform range gating.

5

In order for all elements of the system as described to operate optimally, the system has to be thermally stable. Thermal stability avoids, among other things, undesired wavelength shifts of the optical elements (thermal drift), which would otherwise impair the proper functioning of the optical filters and other elements of the optical chain. Embodiments of the system according to the present invention achieves thermal stability by their design, or by active regulation by means of a temperature control loop with a PID-type controller.

15

WO 2015/004213 A1 discloses various techniques to minimize the amount of ambient light that reaches the pixels during the detection intervals, thus improving the accuracy of the detection of the patterned laser spots. While these techniques have not been disclosed in the context of a LIDAR system, the inventors of the present invention have found that several such techniques yield excellent results when combined with embodiments of the present invention. This is particularly true for the use of narrow bandpass filters at the detector, and the use of adequate optical arrangements to ensure nearly perpendicular incidence of the reflected light onto the filters. The details of these arrangements as they appear in WO 2015/004213 A1 are hereby incorporated by reference. Further features and details are provided hereinafter.

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While various techniques known from WO 2015/004213 A1 may be applied to embodiments of the present invention to minimize the amount of ambient light that reaches the pixels during the detection intervals, a certain amount of ambient light cannot be avoided. In a multi-pixel system, only some of the pixels will be illuminated by reflected spots, while others will be illuminated by residual ambient light only. The signal levels of the latter

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group of pixels can be used to estimate the contribution of the ambient light to the signals in the pixels of interest, and to subtract that contribution accordingly. Additionally or alternatively, background light or ambient light may be subtracted from the detected signal at pixel level. This requires two exposures, one during the arrival of the laser pulse and one in the absence of a pulse.

In some embodiments, the detector may be a high dynamic range detector, i.e. a detector having a dynamic range of at least 90 dB, preferably at least 120 dB. The presence of a high dynamic range sensor, i.e. a sensor capable of acquiring a large amount of photons without saturation while maintaining sufficient discrimination of intensity levels in the darkest part of the scene, is an advantage of the use of such a sensor; it allows for a sensor that has a very long range and yet remains capable of detection objects at short distance (where the reflected light is relatively intense) without undergoing saturation. The inventors have found that the use of a true high dynamic range sensor is more advantageous than the use of a sensor that applies tone mapping. In tone mapping, the sensor linear range is compressed towards the higher resolution. In literature, several compression methods are documented, such as logarithmic compression or multilinear compression (see Figure 5). However, this non-linear compression necessitates relinearisation of the signals before performing logical or arithmetic operations on the captured scene to extract the relief information. The solution according to the invention therefore increases detection accuracy without increasing the computational requirements. It is a further advantage of some embodiments to use a fully linear high dynamic range sensor as presented in Figure 6. A pixel architecture and an optical detector that are capable of providing the desired dynamic range characteristics are disclosed in US patent application publication no. US 2014/353472 A1, in particular paragraphs 65-73 and 88, the content of which is incorporated by reference for the purpose of allowing the skilled person to practice this aspect of the present invention.

Embodiments of the present invention use a high dynamic range pixel. This can be obtained by a sizeable full-well capacity of the charge reservoir or by designs limiting the electronic noise per pixel or by usage of CCD gates that do not add noise at charge transfer, or through a design with a large detection quantum efficiency (DQE) (e.g., in the range of 50% for front illumination or 90% in case of back illumination, also known as back thinning), or by any combination of the listed improvements. Furthermore, the dynamic range can be further enlarged by adding an overflow capacity to the pixel in overlay at its front side (this implementation requires back thinning). Preferably, the pixel design implements an anti-blooming mechanism as described above.

Figure 7 represents a possible dual-well or dual-bin implementation of an envisaged pixel to be used in CMOS technology. The impinging signal is distributed over two charge storages. Each reservoir has a separate transfer gate controlled by an external pulse which is synchronized with the pulse of the laser sources.

An exemplary asymmetric three-well pixel according to the present invention, including anti-blooming circuitry, is schematically presented in Figure 8. The charge storage wells **221, 222, 223** (SN A, SN B, SN C) are connected to a photo-active region (PH) by means of transfer gates (TG A, TG B, TG C), which are controlled to synchronize the active states of the two charge storage wells with the transmission of the projection pulses as described above. The photoactive region (PH) is preferably implemented as a pinned photodiode, which allows for a total depletion of the charges generated in the photoactive region via the transfer gates.

If the capacities of the three charge storage wells are denoted as C1 (first amount of reflected light → SN A), C2 (second amount of reflected light → SN B), and C3 (background light → SN C), the dimensioning is preferably as follows: $C1 > C2 > C3$.

C2 is preferably less than or equal to $2/3$ of C1, and more preferably less than or equal to 50% of C1.

C3 is preferably smaller than or equal to 90% of C2, more
5 preferably smaller than or equal to 70% of C2, and most preferably smaller than or equal to 50% of C2.

The inventors have further found that to obtain a useful operating range (between the lowest detectable light level and the light
10 level at which saturation occurs), C2 may be dimensioned smaller than C1 because the reflected amount of light that the second well will receive is always small: either the reflecting object is far away and the signal is strongly reduced because of the distance (though the bulk of the reflected light arrives at SN B during the
15 second time window, due to the distance), or the reflecting object is nearby and the bulk of the reflections arrives in SN A during the first time window.

When used for background subtraction, C3 may be dimensioned as the
20 smallest of the three wells as the background light is strongly reduced by the narrowband filter (preferably with optics or other means to make the incident light nearly perpendicular with respect to the filter, as described in more detail below). The narrowband may have an exemplary passband bandwidth of up to 20 nm,
25 preferably up to 10 nm, and more preferably up to 5 nm.

The transfer gates are preferably placed on one edge of the photoactive region (in particular, the pinned photodiode), so as to achieve the same amount of delay for each well collection
30 regardless of where the light falls inside the pixel.

In a preferred configuration, the data is captured by a photodiode element, more specifically a pinned photodiode, and the data is stored immediately through a transfer gate, on the top plate of a
35 MOSFET (acting as a high-density capacitor), the bottom plates of which are referenced to ground. In this way, the data is kept in the *voltage domain*. This may be understood with reference to

Figure 8 by looking at the operation of transfer gate TG A and storage node SN A: the photodiode converts the photons into electrons, the transistor acting as TG A is opened, whereupon the electrons are stored at SN A, which directly increases the voltage at the read-out side.

This configuration is based on the insight of the inventors that by working in the voltage domain, the implementation can be made more compact and allows a better trade-off between sensitivity and sensor resolution.

The preferred configuration disclosed herein thus differs significantly from the configurations known in the art that use photogates as photo sensing elements and MOSFET channels as storage elements to accumulate information in the *charge domain*. Those known configurations have two pitfalls: firstly, the required number of gates and transistor becomes large and this limits the resolution of the sensor. Secondly, information accumulation in the *charge domain* raises the issue of *transfer of the charges* from one node to the other, or from one node to the read-out amplifier; if the transfer is incomplete, any data left in the storage nodes will create a ghost image appearing in the next frame. The known solutions to that problem (use of pinned transistors, buried MOSFET) limit the manufacturing of time-of-flight sensors to very specific manufacturing processes.

It is an advantage of the configuration disclosed herein that it enables the production of high-resolution time-of-flight sensors using CMOS technology, bringing the advantages of CMOS processing to this application field (including deep submicron digital processing and on-chip sequencing).

Figure 9 schematically represents an embodiment of the pixel according to the present invention, showing a first way of obtaining the asymmetry of the wells. As shown in Figure 9, the first well **221** (the depletion zone on the A-signal side) has been

made larger than the second well **222** (the depletion zone on the B-signal side) during the semiconductor fabrication process.

Figure 10 schematically represents an embodiment of the pixel according to the present invention, showing a second way of obtaining the asymmetry of the wells. In this case, both semiconductor wells **221**, **222** are of identical size, but an additional capacitor is provided on the A-signal side to increase the effective capacity of the first well **221**.

In systems according to the present invention, the read-outs of the ranging nodes **221** (SN A), **222** (SN B) are preferably single-step read-outs. The read-out transistors are preferably directly connected to the storage capacity (sensing node) and can be read out in parallel. This arrangement results in higher speed and lower noise or parasitic capacity compared to a two-step read-out; in addition, the fill factor is improved, which is important due to the low number of ranging photons that may be obtained from a semiconductor laser projector.

The third sensing node **223** (SN C) and its associated transfer gate (TG C) may be used in an anti-blooming arrangement. When the sensing nodes **221**, **222** are full (saturated), the antiblooming gate (TG C) may be used to draw away the flooding electrons in order not to contaminate the surrounding pixels, which may be used to perform other functions as described above (e.g., range gating, background light sensing for background subtraction, triangulation, ...). Additionally, the anti-blooming gate (TG C) may be used to draw away the electrons which have not yet diffused to sensing node A prior to opening sensing node B, as will now be explained in more detail.

It is an object of embodiments of the present invention to reduce the latency of the diffusion of electrons towards the sensing nodes. An excessive latency may cause residual electrons to be left on the photodiode (i.e., not fully diffused) between the recordings of SN A and SN B; accordingly, remaining electrons from

sensing node A (SN A, **221**) could diffuse to sensing node B (SN B, **222**) when transfer gate A (TG A) is closed, and contaminate the second signal. Embodiments of the present invention reduce or avoid this effect by providing a flush pulse with duration T_p , to drive the residual electrons away over the anti-blooming gate by activating the anti-blooming gate (TG C). When the anti-blooming gate (TG C) is powered (by applying a voltage), those remaining electrons are pulled away. After the pulse T_p , sensing node B (SN B) is opened by activating transfer gate B (TG B) to record the second part of the reflected signals. T_p is dimensioned in function of the diffusion characteristics of the semiconductor material and the pulse duration of the ranging signal. An optimum must be sought between avoiding contamination of reading B and missing too many of the useful reflected photons as required for the ranging formula. Preferably, T_p is between 10 ns and 200 ns.

Figures 11-13 illustrate cameras that may be used in embodiments of the invention, where the light radiation source emits monochromatic light and the at least one detector is equipped with a corresponding narrow bandpass filter and optics arranged so as to modify an angle of incidence onto said narrow bandpass filter, to confine said angle of incidence to a predetermined range around a normal of a main surface of said narrow bandpass filter, said optics comprising an image-space telecentric lens. The term "camera" is used herein as a combination of a sensor and associated optics (lenses, lens arrays, filter). In particular, in Figure 12, the optics further comprise a minilens or microlens array arranged between the image-space telecentric lens and the at least one detector, such that individual minilenses of the minilens array focus incident light on respective light-sensitive areas of individual pixels of the at least one detector. It is an advantage of this one-minilens-per-pixel (or one-microlens-per-pixel) arrangement that the loss due to the fill factor of the underlying sensor can be reduced, by optically guiding all incident light to the light-sensitive portion of the pixels.

These examples all result in radiation travelling a substantially equal length through the filter medium or in other words in that the incident radiation is substantially orthogonal to the filter surface, i.e. it is confined to an angle of incidence within a predetermined range around the normal of the filter surface, thus allowing in accurate filtering within a narrow bandwidth to e.g. filter the daylight, the sunlight and in order to for the spots to surpass the daylight.

The correction of the angle of incidence is of particular importance in embodiments of the present invention where the entire space around a vehicle is to be monitored with a limited number of sensors, for instance 8 sensors, such that the incident rays may extend over a solid angle of for example 1×1 rad.

Figure 11 schematically illustrates a first optical arrangement of this type. It comprises a first lens **1030** and a second lens **1040**, with approximately the same focal length f , in an image space telecentric configuration. That means that all chief rays (rays passing through the center of the aperture stop) are normal to the image plane. An exemplary numerical aperture of 0.16 corresponds to a cone angle of 9.3° (half cone angle). The maximum incidence angle on the narrow bandpass filter **1060**, arranged between the lens system **1030-1040** and the sensor **102**, would thus be 9.3° .

As illustrated in Figure 12, the preferred design consists of a tandem of two lenses **1130**, **1140** with approximately the same focal length f , in an image-space telecentric configuration (the configuration is optionally also object-space telecentric), a planar stack of mini-lens array **1150**, a spectral filter **1160** and a CMOS detector **102**. Since the center O of the first lens **1130** is in the focus of the second lens **1140**, every ray that crosses O will be refracted by the second lens **1140** in a direction parallel to the optical axis. Consider now a particular laser spot S **1110** located at a very large distance as compared to the focal length of the first lens **1130**. Thus the image of this spot **1110** by the first lens **1130** is a point P located close to the focal plane of

this lens, thus exactly in the middle plane of the second lens **1140**. The light rays that are emitted from the spot **S 1110** and captured by the first lens **1130** form a light cone that converges towards the point **P** in the second lens **1140**. The central axis of this light cone crosses the point **O** and is refracted parallel the optical axis and thus perpendicular to the spectral filter **1160** so as to achieve optimal spectral sensitivity. Hence, the second lens **1140** acts as a correcting lens for the angle of the incident light beam. The other rays of the cone can also be bent in a bundle of rays parallel to the optical axis by using a small convex mini-lens **1150** behind the second lens **1140** in such a way that the point **P** is located in the focal point of the mini-lens **1150**. In this way all the imaging rays of the spot **S 1110** are bent in a direction nearly perpendicular to the spectral filter. This can now be done in front of every pixel of the CMOS detector separately by using an array of mini-lenses positioned in front of every pixel. In this configuration, the minilenses have an image-telecentric function. The main advantage is that the pupil of the first lens **1030** can be enlarged, or the aperture can be eliminated while compensating for the increase in spherical aberration by a local correction optics in the mini-lens **1150**. In this way the sensitivity of the sensor assembly can be improved. A second mini-lens array (not shown in Figure 12) may be added between the spectral filter **1160** and the CMOS pixels **102**, to focus the parallel rays back to the photodiodes of the pixels so as to maximize the fill factor.

For the first and second lenses **1130**, **1140**, commercially available lenses may be used. The skilled person will appreciate that lenses typically used in other smart phone cameras or webcams of comparable quality can also be used. The aforementioned iSight camera has a 6 x 3 mm CMOS sensor with 8 megapixels, 1.5 μm pixel size, a very large aperture of $f/2.2$, an objective focal length of about $f = 7\text{ mm}$, and a pupil diameter about 3.2 mm. The viewing angle is of the order of 1 rad x 1 rad. If we assume that the resolution of the camera is roughly the pixel size (1.5 micron), we can conclude (from Abbe's law) that the aberrations of the lens

are corrected for all the rays of the viewing angle selected by the aperture.

Figure 13 illustrates a variation of the arrangement of Figure 12, optimized for manufacturing in a single lithographic process. The first lens **1230** is similar to the first lens **1130** of the previous embodiment, but the angle-correcting second lens **1140** is replaced by a Fresnel lens **1240** with the same focal length f and the mini-lens arrays **1150** by Fresnel lens arrays **1250**. The advantage is that they are completely flat and can be produced by nano-electronics technology (with discrete phase zones). A second mini-lens array **1270** may be added between the spectral filter **1260** and the CMOS pixels **102**, to focus the parallel rays back to the photodiodes of the pixels so as to maximize the fill factor. Thus the camera is essentially a standard camera as the iSight but in which the CMOS sensor is replaced by a specially designed multilayer sensor in which all the components are produced in one integrated block within the same lithographic process. This multilayer sensor is cheap in mass production, compact, robust and it need not be aligned. Each of these five layers **1240**, **1250**, **1260**, **1270**, **102** has its own function to meet the requirements imposed by the present invention.

As the minimal angle of a cone generated by a lens of diameter d is of the order of λ/d , with λ the wavelength of the light, the minimal cone angle is 1/10 radian for a mini-lens diameter $d = 8.5 \mu\text{m}$ and $\lambda = 850 \text{ nm}$. With a good quality spectral interference filter this corresponds to a spectral window of about 3 nm.

Figure 14 illustrates an alternative optical arrangement, comprising a dome **1310** (e.g., a bent glass plate) with the narrow bandpass filter **1320** disposed on its inside (as illustrated) or outside (not illustrated). The advantage of disposing the filter **1320** on the inside of the dome **1310**, is that the dome **1310** protects the filter **1320** from outside forces. The dome **1310** and the filter **1320** optically cooperate to ensure that incident light passes through the filter **1320** along a direction that is

substantially normal to the dome's surface. Fish-eye optics **1330** are provided between the dome-filter assembly and the sensor **102**, which may be a CMOS or a CCD sensor or SPAD array. The fish-eye optics **1330** are arranged to guide the light that has passed
5 through the dome-filter assembly towards the sensitive area of the sensor.

Optionally, further fish-eye optics are provided at the projector. In a specific embodiment, a plurality of VCSELs are mounted in a 1
10 x n or a m x n configuration, whereby an exit angle of the laser beam can be realized over a spatial angle of m x 1 rad in height and n x 1 rad in width.

In some embodiments of the present invention, the intensity of the
15 spots can be kept substantially constant over the full depth range, by applying a stepped or variable attenuation filter at the detector. Alternatively or in addition, also a non-symmetrical lens pupil can be provided for weakening the intensity of spots closer to the detector, while the intensity of the spots further
20 away from the detector are received at full intensity. In this way clipping of the detector is avoided and the average intensity can be made substantially the same for all spots.

In some embodiments, the radiation source can be a VCSEL that can
25 be split in different zones, whereby the laser ON time is controlled for the different zones. The images of the spots can thus be controlled to have a constant intensity, e.g. $2/3^{\text{rd}}$ of the A/D range. Alternatively, the driving voltage can be driven over the array of spots as function of the height, again to obtain a
30 constant intensity. Such controlling can be referred to as a saturation avoidance servoing loop. The different VCSELs within the array can be controlled individually for intensity, varying the intensity of the individual VCSELs in the pattern while projected simultaneously.

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In some other embodiments of the present invention, a micro prism matrix can be used in front of the narrow bandwidth filter, such

that the radiation is incident within an angle of incidence between +9° and -9° on the filter. This allows to obtain narrow bandwidth filtering. The prism matrix can for example be made by plastic moulding.

5

In the arrangements of Figures 11-14, the characteristics of the optics will result in a non-planar focal plane. To compensate this effect, the picture elements of the detector may be arranged on a substrate having a curvature that follows the focal plane of the optics. As a result, the reflected and filtered spots will be in focus, regardless of where they reach the detector. The desired curvature of the substrate of the detector can be obtained by using flex-chip technology, or by composing the substrate by combining differently oriented tiles. This solution is schematically illustrated in Figure 15, which shows telecentric optics **1330**, followed by a narrow band-pass filter **1360**, and a curved pixel layer **102**, the curvature of which is adapted to follow the shape of the focal plane of the telecentric optics **1330**.

20

When it is not possible (or not desirable) to arrange the optics in such a way as to ensure that light rays following different paths all pass through the narrow bandpass filter under the same (perpendicular) angle, the problem of having different filter characteristics with different angles of incidence may be resolved at the source. In particular, the VCSEL array may be configured such that different spots have different respective wavelengths. This configuration may be obtained by using a tiled laser array, or by providing means for modulating the wavelength of individual VCSELs in the VCSEL array. This solution is schematically illustrated in Figure 16, which shows a narrow band-pass filter **1460** arranged before the optics **1430** and the sensor array **102**. For clarity purposes and without loss of generality, two different angles of incidence with different respective wavelengths (λ_1 , λ_2) have been indicated on the Figure. The different wavelengths (λ_1 , λ_2) of the light sources are chosen to correspond to the maximum of

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the passband of the narrow bandpass filter under their respective angles of incidence.

5 In some embodiments of the present invention, the intensity of the spots can be kept substantially constant over the full depth range, by applying a stepped or variable attenuation filter at the detector. Alternatively or in addition, also a non-symmetrical lens pupil can be provided for weakening the intensity of spots closer to the detector, while the intensity of the spots further
10 away from the detector are received at full intensity. In this way clipping of the detector is avoided and the average intensity can be made substantially the same for all spots.

In some embodiments, the radiation source can be a VCSEL array
15 that can be split in different zones, whereby the laser ON time is controlled for the different zones. In some embodiments, the radiation source can be a VCSEL array whereby the laser ON time is controlled at individual laser level. The images of the spots can thus be controlled to have a constant intensity, e.g. $2/3^{\text{rd}}$ of the
20 A/D range. Alternatively, the driving voltage can be driven over the array of spots as function of the height, again to obtain a constant intensity. Such controlling can be referred to as a saturation avoidance servoing loop. The different VCSELs within the array can be controlled in groups or individually for
25 intensity, varying the intensity of the individual VCSELs in the pattern while projected simultaneously.

In some other embodiments of the present invention, a micro prism matrix can be used in front of the narrow bandwidth filter, such
30 that the radiation is incident within an angle of incidence between $+9^\circ$ and -9° on the filter. This allows to obtain narrow bandwidth filtering. The prism matrix can for example be made by plastic moulding.

35 In embodiments of the present invention, e.g. where active suspension vehicle applications are envisaged, the projection of

the spot pattern is advantageously directed downwards, i.e. towards the road.

A system according to the invention may include an implementation
5 of steps of the methods described above in dedicated hardware
(e.g., ASIC), configurable hardware (e.g., FPGA), programmable
components (e.g., a DSP or general purpose processor with
appropriate software), or any combination thereof. The same
component(s) may also include other functions. The present
10 invention also pertains to a computer program product comprising
code means implementing the steps of the methods described above,
which product may be provided on a computer-readable medium such
as an optical, magnetic, or solid-state carrier.

15 The present invention also pertains to a vehicle comprising the
system described above.

Embodiments of the present invention may be used advantageously in
a wide variety of applications, including without limitation
20 automotive applications, industrial applications, gaming
applications, and the like, and this both indoor and outdoor, at
short or long range. In some applications, different sensors
according to embodiments of the present invention may be combined
(e.g., daisy-chained) to produce panoramic coverage, preferably
25 over a full circle (360° field of view).

While the invention has been described hereinabove with reference
to separate system and method embodiments, this was done for
clarifying purposes only. The skilled person will appreciate that
30 features described in connection with the system or the method
alone, can also be applied to the method or the system,
respectively, with the same technical effects and advantages.
Furthermore, the scope of the invention is not limited to these
embodiments, but is defined by the accompanying claims.

Claims

1. A system (200) for determining a distance to an object comprising:

- 5 - a semiconductor light source (210) arranged for projecting a pattern of discrete spots of laser light towards said object in a periodically repeated sequence of pulses;
- a detector (220) comprising a plurality of CMOS picture elements, said detector (220) being configured for detecting
10 light representing said pattern of discrete spots as reflected by said object in synchronization with said sequence of pulses, said detector (220) being provided with a narrowband filter; and
- processing means (240) configured to calculate said distance
15 to said object as a function of exposure values generated by said picture elements in response to said detected light;
- wherein said picture elements (220) are configured to generate said exposure values by accumulating, for all of the pulses of said sequence, a first amount of electrical charge representative
20 of a first amount of light reflected by said object during a first predetermined time window (10) and a second electrical charge representative of a second amount of light reflected by said object during a second predetermined time window (20), said second predetermined time window (20) occurring after said first
25 predetermined time window (10);
- wherein each of said plurality of picture elements comprises at least two charge storage wells (221, 222), and wherein said detecting of said first amount of light and said detecting of said second amount of light occurs at respective ones of said at least
30 two charge storage wells (221, 222); and
- wherein each of said plurality of picture elements comprises at least one further charge storage well (223) configured to perform a function different from said detecting of said first amount of light and said detecting of said second amount of light, said at
35 least one further charge storage well (223) having a charge storage capacity that is smaller than a charge storage capacity of said at least two charge storage wells (221, 222).

2. The system according to claim 1, wherein said function comprises acquiring a two-dimensional image.

5 3. The system according to claim 1, wherein said function comprises acquiring background light values.

4. The system according to claim 1, wherein said function comprises accumulating, for all of the pulses of said sequence, a
10 third amount of electrical charge representative of a third amount of light during a third predetermined time window.

5. The system according to claim 1, wherein said first charge storage well (221) used for said detecting of said first amount of
15 light has a charge storage capacity that is greater than said second charge storage well (222) used for said detecting of said second amount of light.

6. The system according to any of the preceding claims, further
20 configured to perform the projecting and the detecting for at least two consecutive sequences of pulses, each of the sequences being operated with a different duration of the first predetermined time window and the second predetermined time window.

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7. The system according to any of claims 1-6, wherein said first predetermined time window and said second predetermined time window are of substantially equal duration and occur back-to-back.

30 8. The system according to any of the preceding claims, further configured to interleave said first and second predetermined time windows with time windows during which said plurality of picture elements are used in said function different from said detecting of said first amount of light and said detecting of said second
35 amount of light.

9. A vehicle comprising a system (100) according to any of the previous claims arranged to operatively cover at least a part of an area surrounding said vehicle.

5 10. A camera, the camera comprising a system (100) according to any of claims 1 to 8, whereby the system (100) is adapted to add 3D information to the camera image based on information obtained from the system, making it possible to create a 3D image.

10 11. A method for determining a distance to an object, the method comprising:

- using a semiconductor light source (210) to project (110) a pattern of discrete spots of laser light towards said object in a periodically repeated sequence of pulses;
- 15 - using a detector (220) comprising a plurality of CMOS picture elements to detect (120; 130) light representing said pattern of discrete spots as reflected by said object in synchronization with said sequence of pulses, said detector (220) being provided with a narrowband filter; and
- 20 - calculating (140) said distance to said object as a function of exposure values generated by said picture elements in response to said detected light;

wherein said picture elements (220) generate said exposure values by accumulating, for all of the pulses of said sequence, a first
25 amount of electrical charge representative of a first amount of light reflected by said object during a first predetermined time window (10) and a second amount of electrical charge representative of a second amount of light reflected by said object during a second predetermined time window (20), said second
30 predetermined time window (20) occurring after said first predetermined time window (10);

wherein each of said plurality of picture elements comprises at least two charge storage wells, and wherein said detecting of said first amount of light and said detecting of said second amount of
35 light occurs at respective ones of said at least two charge storage wells;

and wherein each of said plurality of picture elements comprises at least one further charge storage well (223) configured to perform said function different from said detecting of said first amount of light and said detecting of said second amount of light, said at least one further charge storage well (223) having a charge storage capacity that is smaller than a charge storage capacity of said at least two charge storage wells (221, 222).

12. The method according to claim 11, wherein said function comprises acquiring a two-dimensional image.

13. The method according to claim 11, wherein said function comprises acquiring background light values.

14. The method according to claim 11, wherein said function comprises accumulating, for all of the pulses of said sequence, a third amount of electrical charge representative of a third amount of light during a third predetermined time window.

15. The method according to any of claims 11-14, wherein said first predetermined time window and said second predetermined time window are of substantially equal duration and occur back-to-back.

16. The method according to any of claims 11-15, wherein said projecting (110), said detecting (120; 130), and said calculating (140) are repeated periodically.

17. The method according to any of claims 11-16, wherein said first and second predetermined time windows are interleaved with time frames during which said plurality of picture elements are used in said function different from said detecting of said first amount of light and said detecting of said second amount of light.

18. A computer program product comprising code means configured to cause a processor to carry out the method according to any of claims 11-17.

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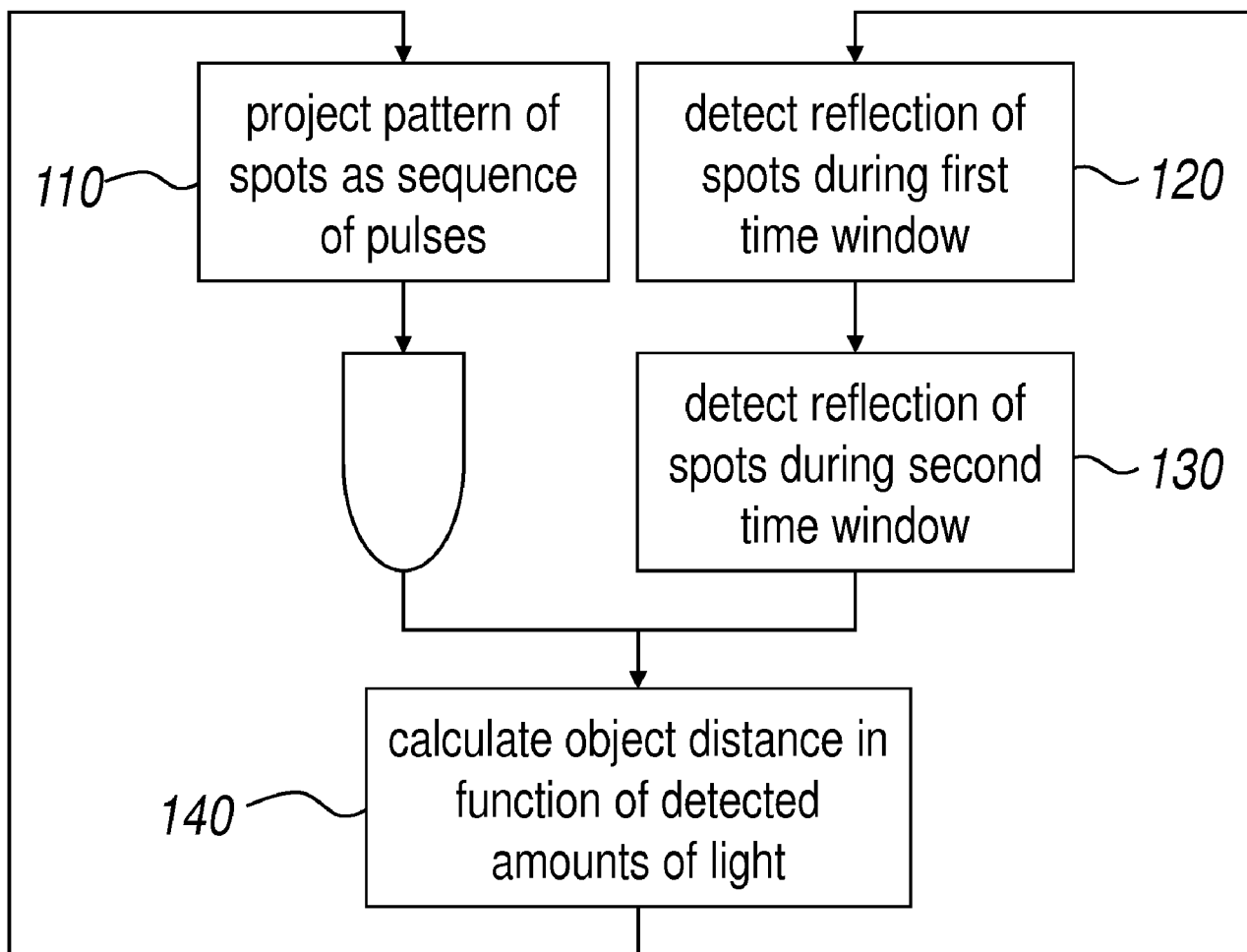


Fig. 1

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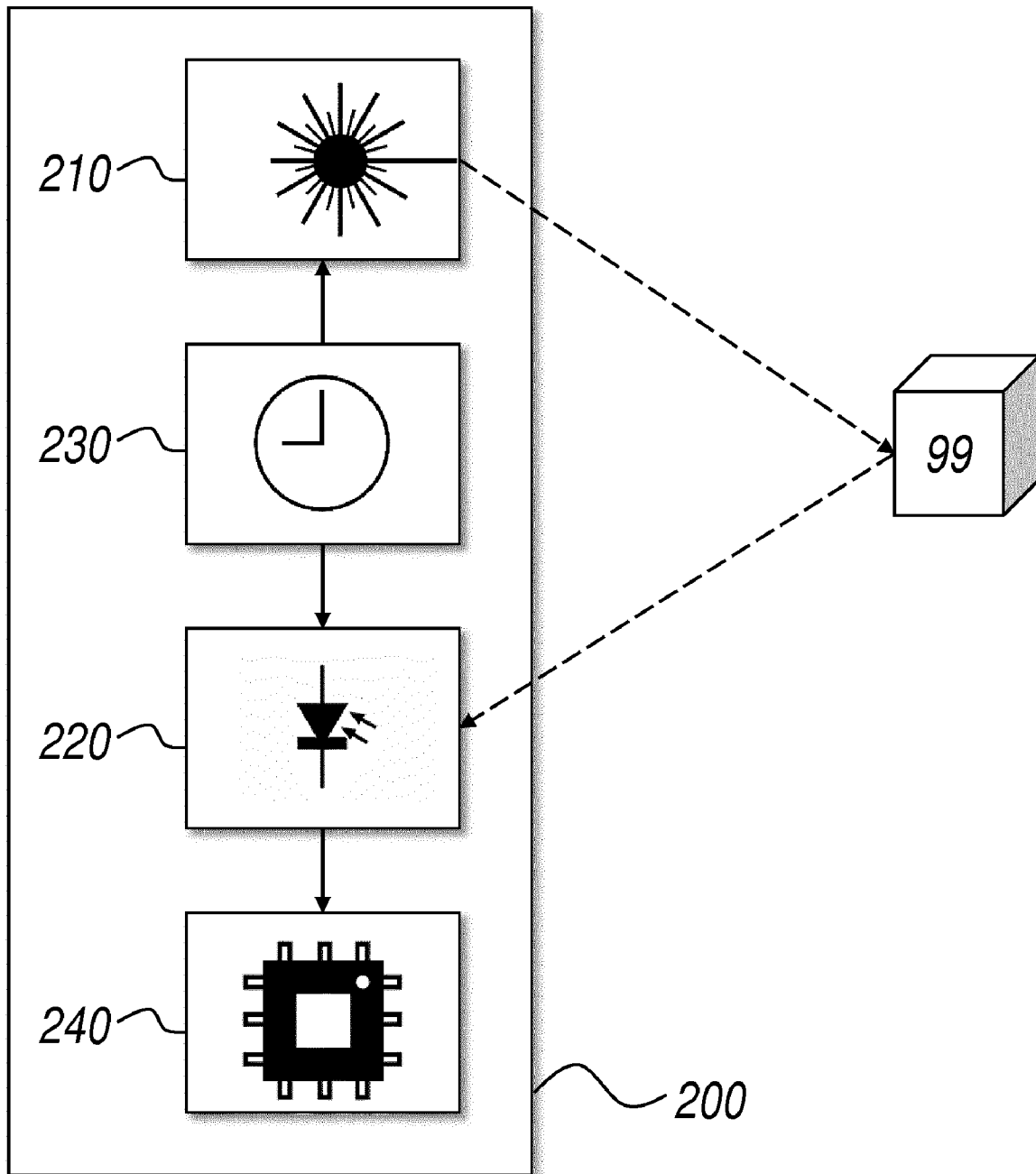


Fig. 2

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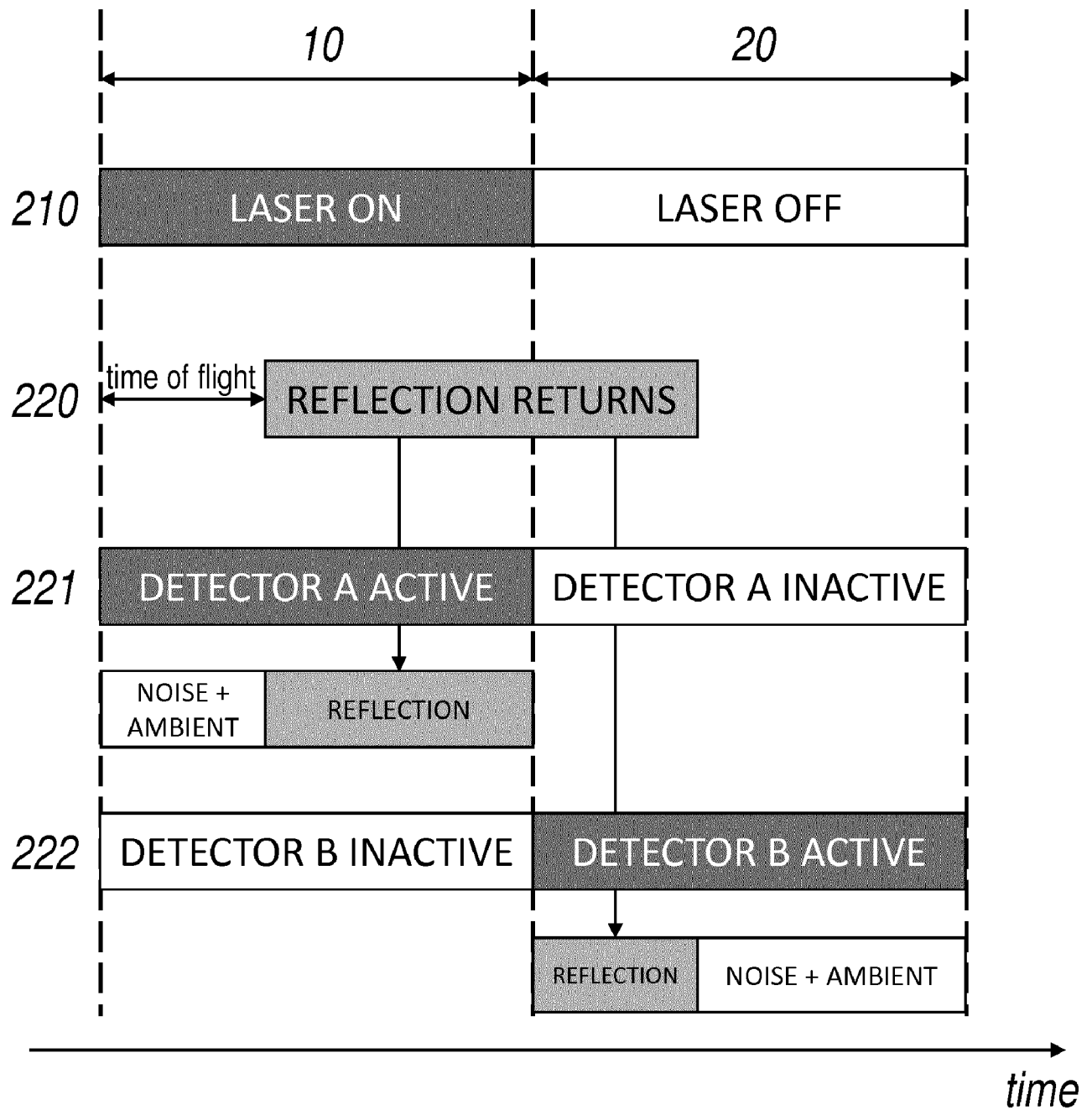


Fig. 3a

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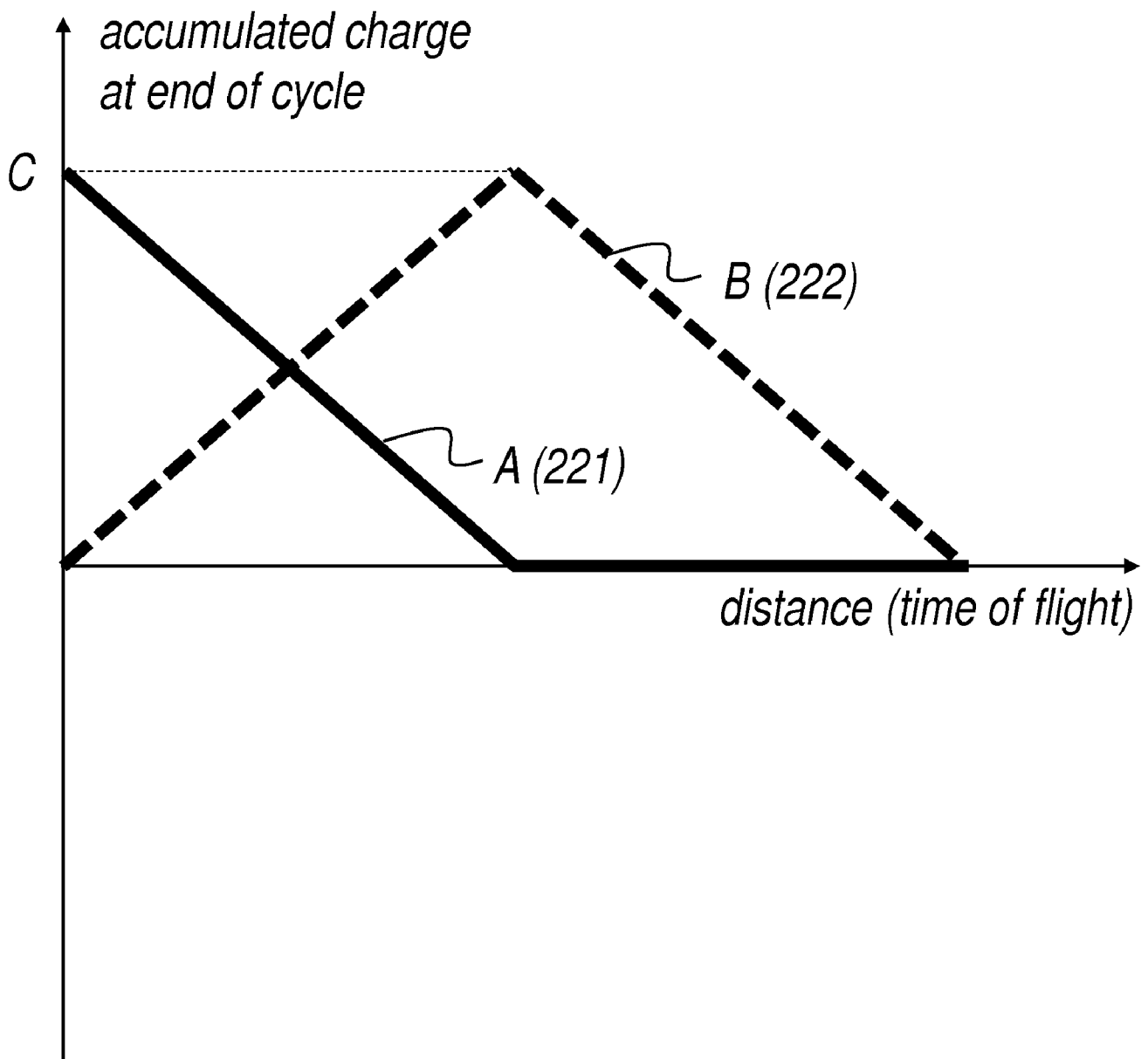


Fig. 3b

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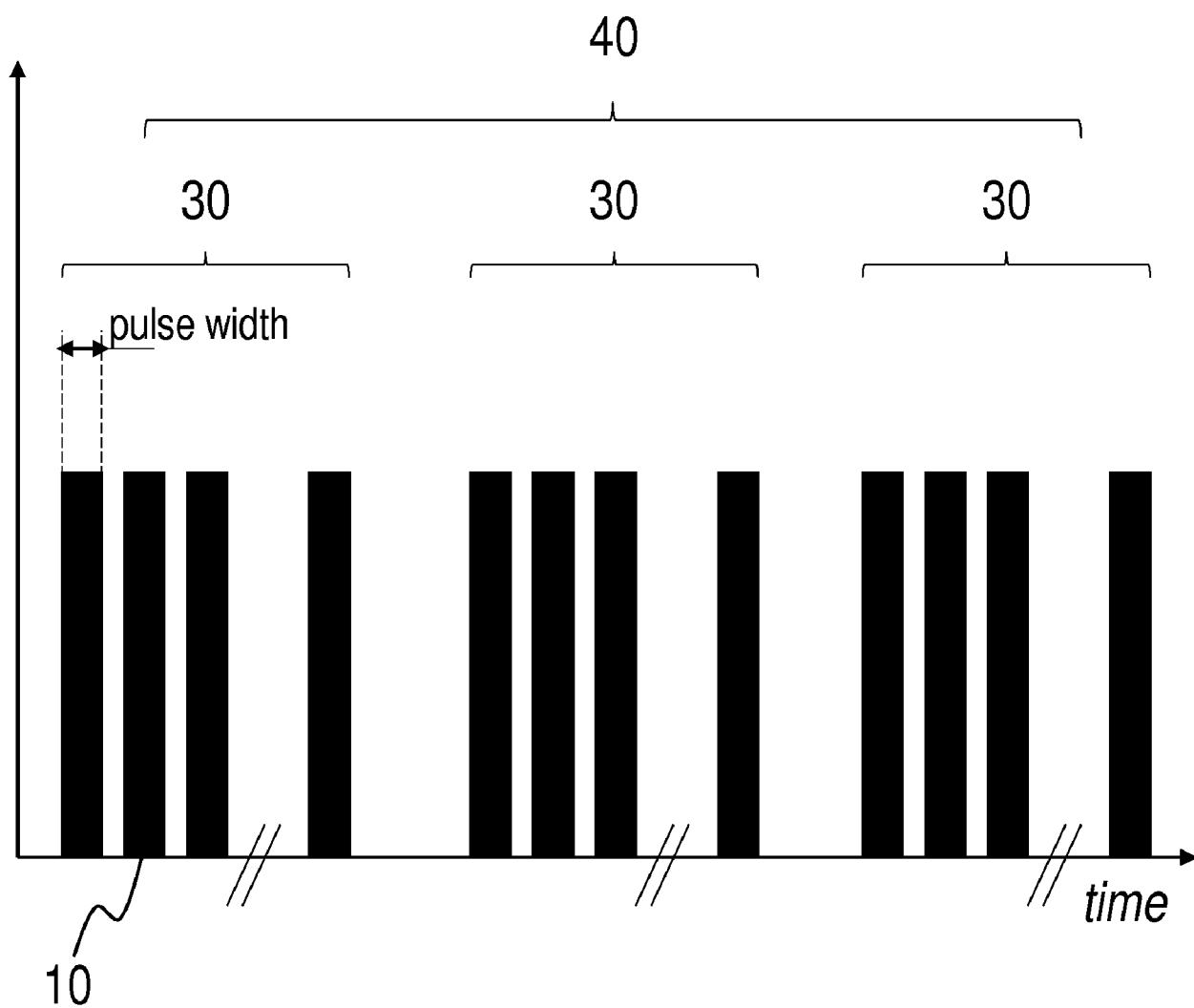


Fig. 3c

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		FRAME 1										FRAME 2									
P		P		P		P						P		P		P					
I	A	A		A		A						A		A		A					
	B		B		B		B					B		B		B					

Fig. 4a

		FRAME 1										FRAME 2									
P		P				P						P				P					
I	A	A		A-		A		A-				A		A-		A		A-			
	B		B		B-		B		B-			B		B-		B		B-			

Fig. 4b

		FRAME 1										FRAME 2									
P		P				P						P				P					
I	A	A				A						A				A					
	B		B			B						B				B					
	C			C			C						C				C				

Fig. 4c

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		FRAME 1										FRAME 2									
P		P		P		P						P		P		P					
I	A	A		A		A						A		A		A					
	B		B		B		B						B		B		B				
	C							C	C	C							C	C	C		

Fig. 4d

		FRAME 1										FRAME 2									
P		P		P		P		P													
I	A	A		A		A		A				A	A	A	A	A	A				
	B		B		B		B		B												

Fig. 4e

		FRAME 1, τ_1										FRAME 2, τ_2									
P		P		P		P		P				P		P		P					
I	A	A		A		A		A				A		A		A					
	B		B		B		B		B				B		B		B		B		

Fig. 4f

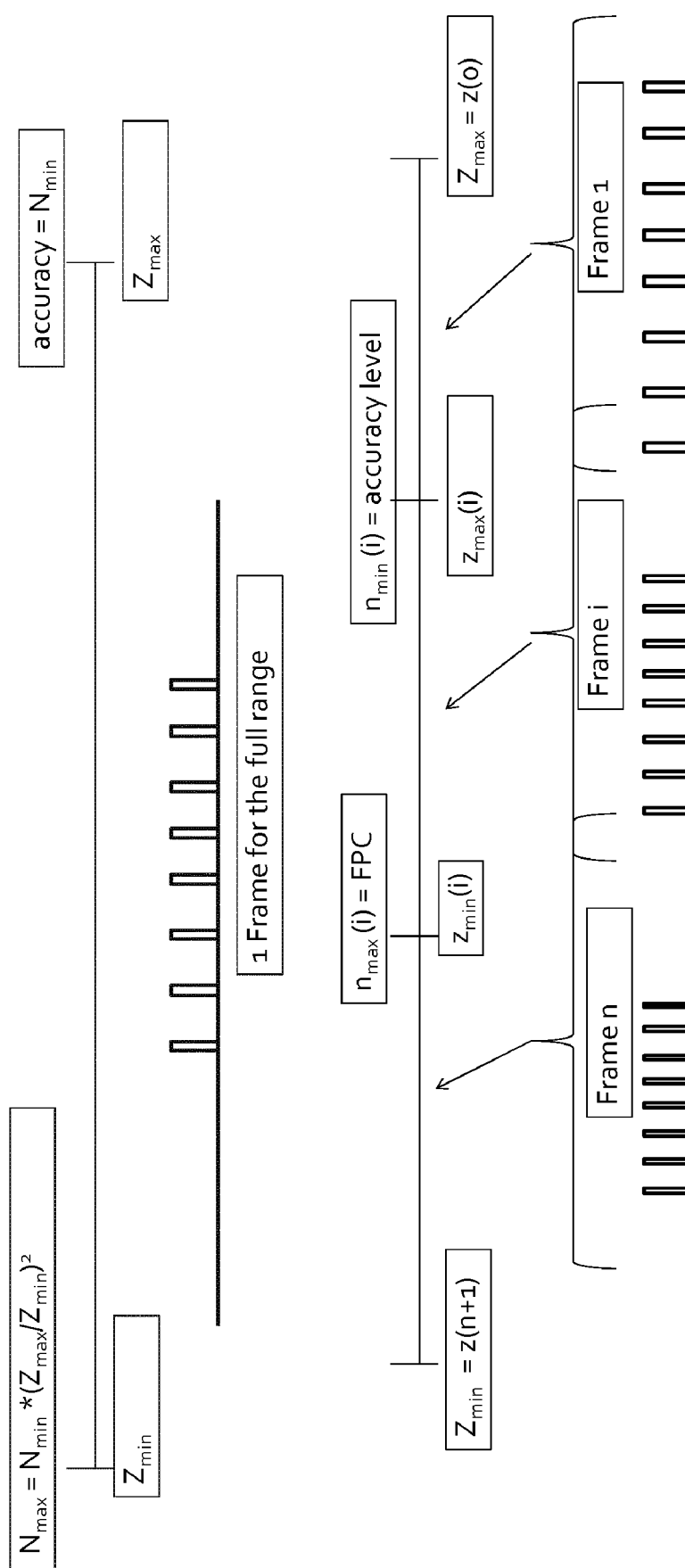


Fig. 4g

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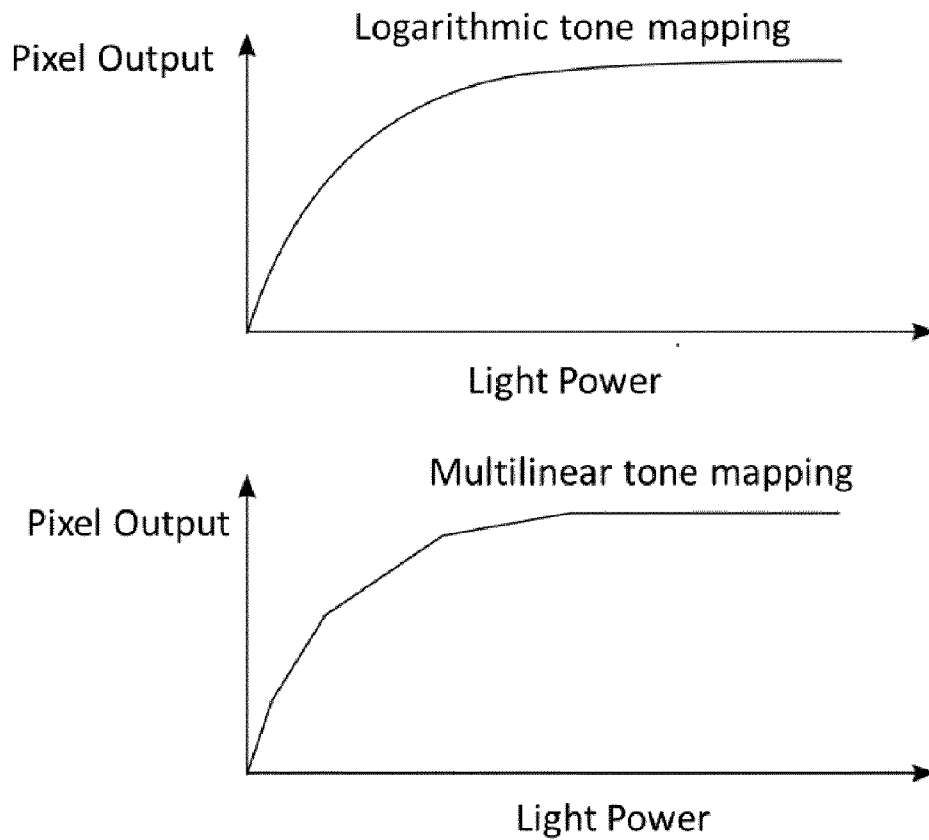


Fig. 5

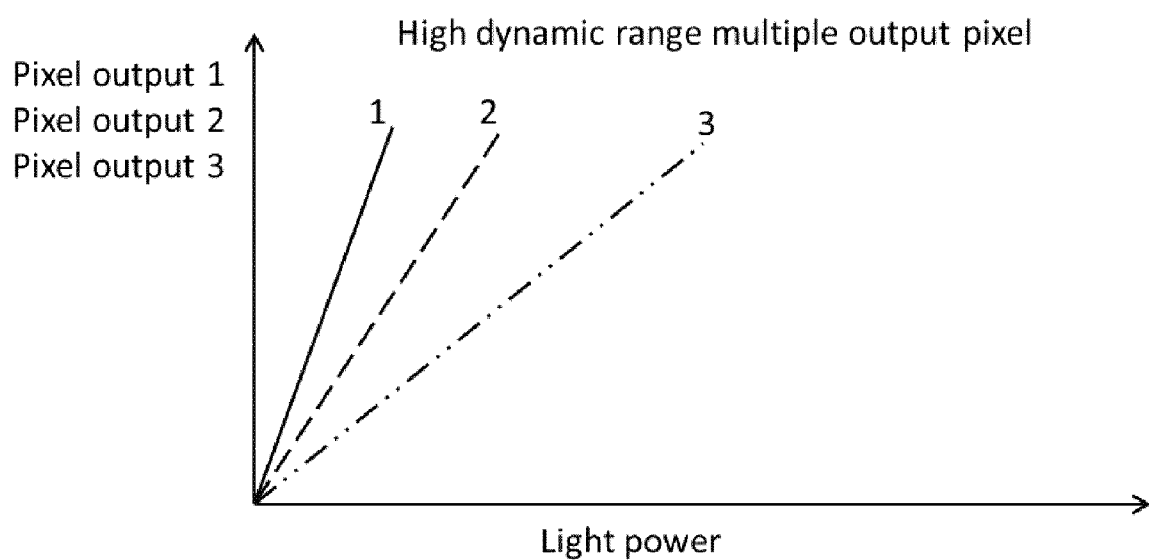


Fig. 6

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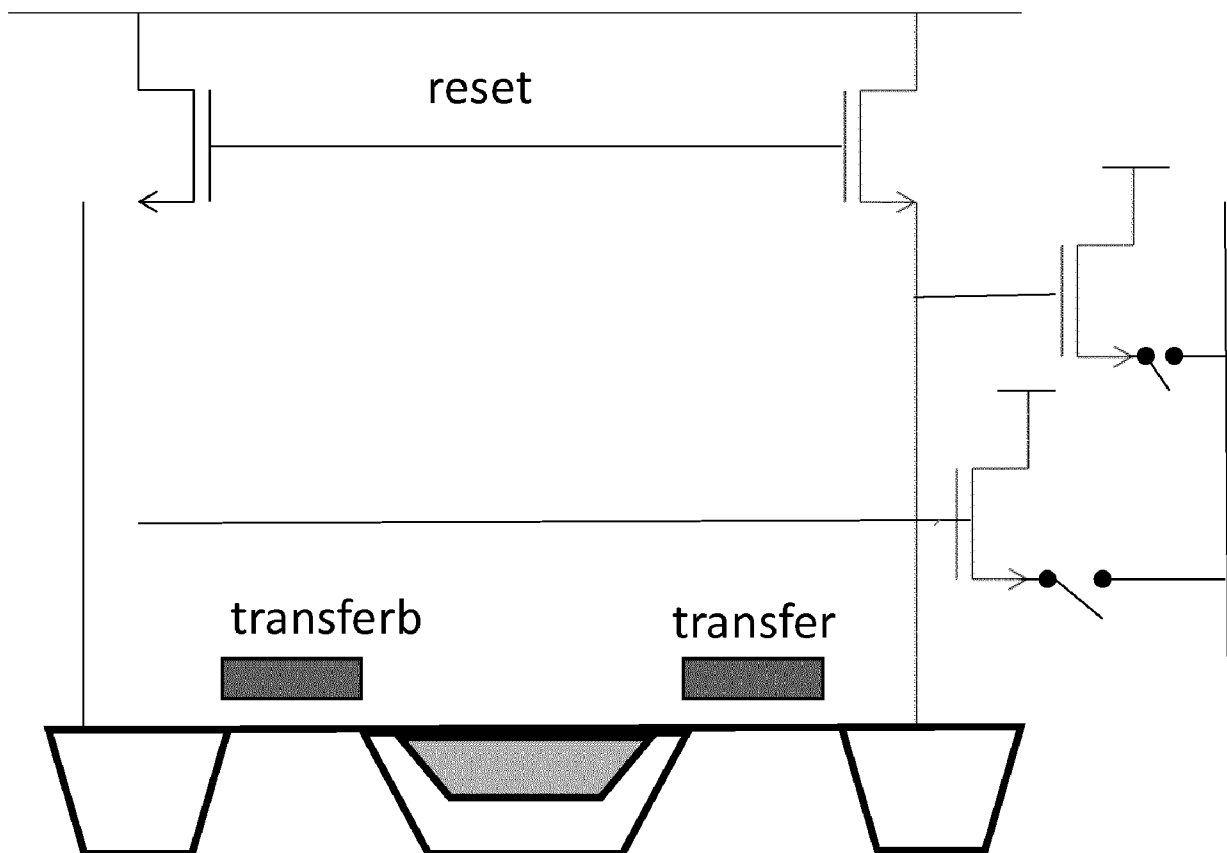


Fig. 7

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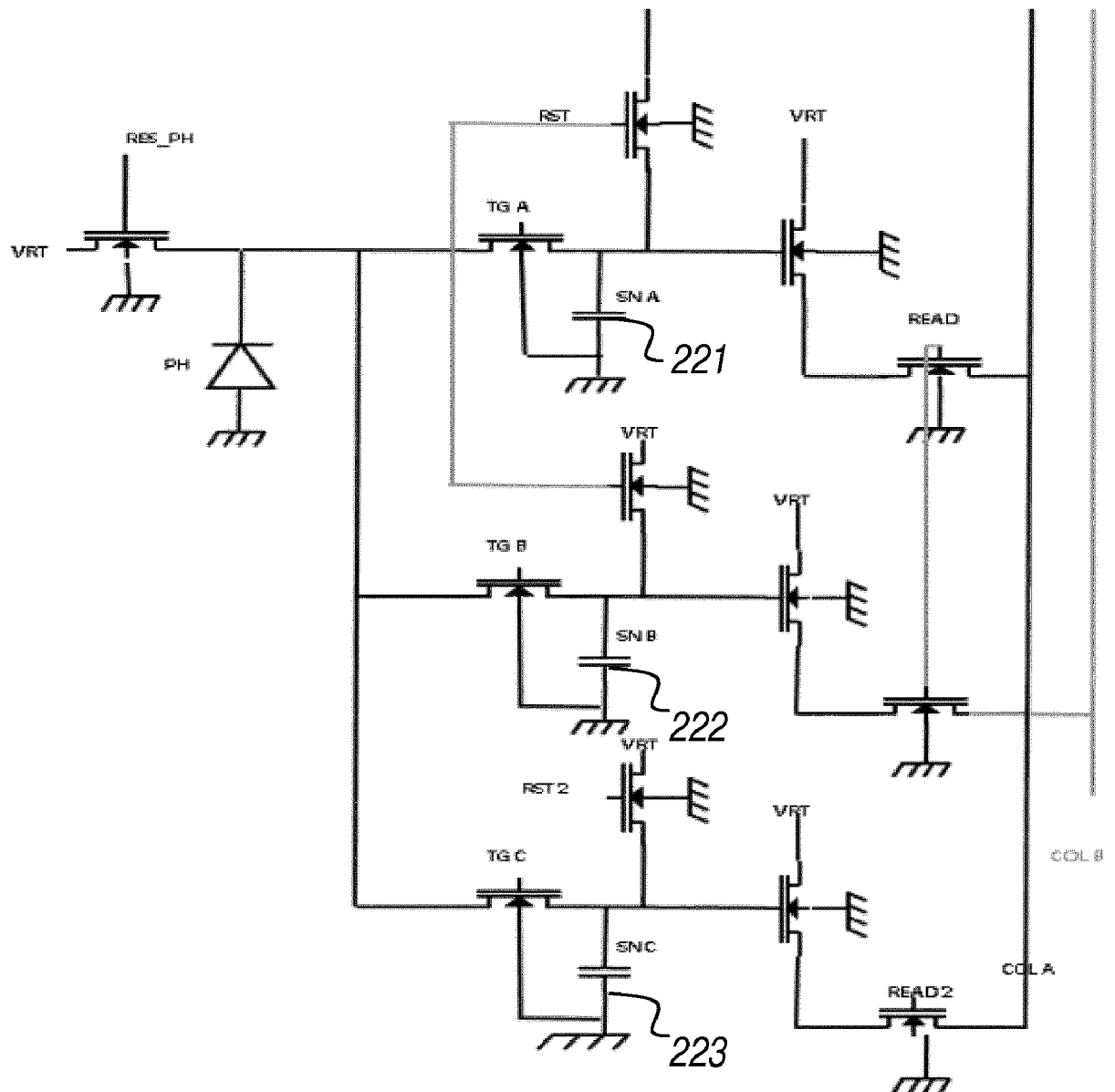


Fig. 8

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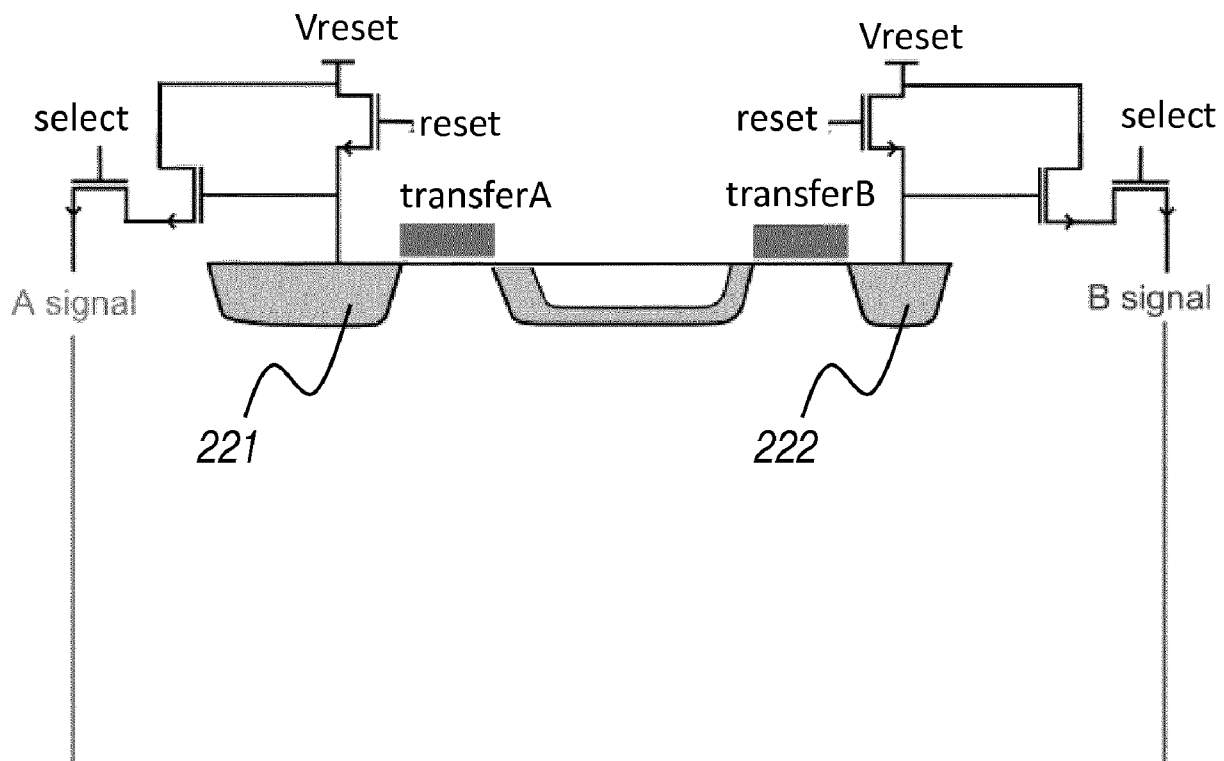


Fig. 9

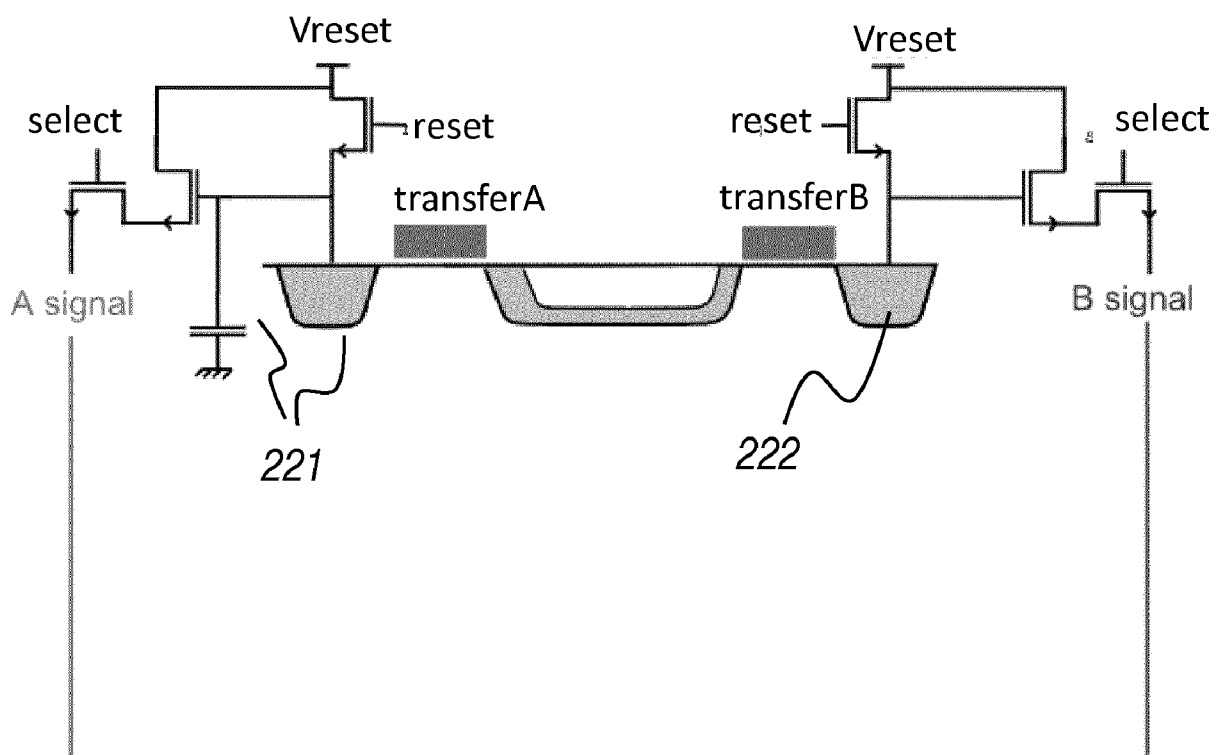


Fig. 10

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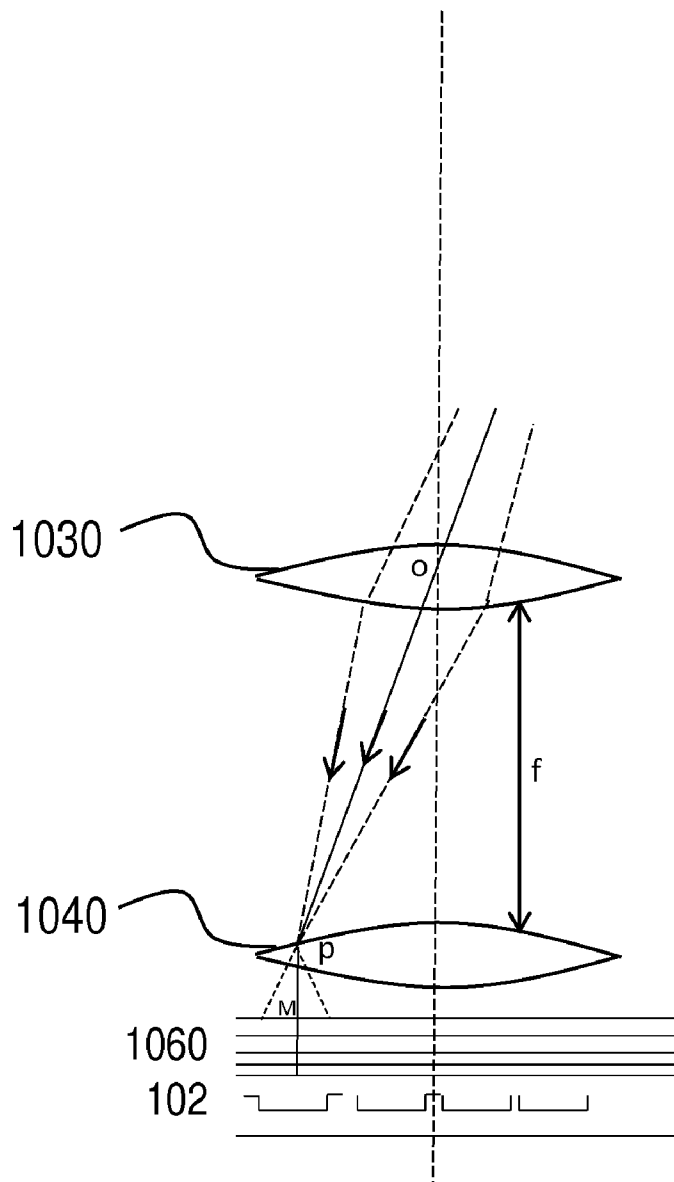


Fig. 11

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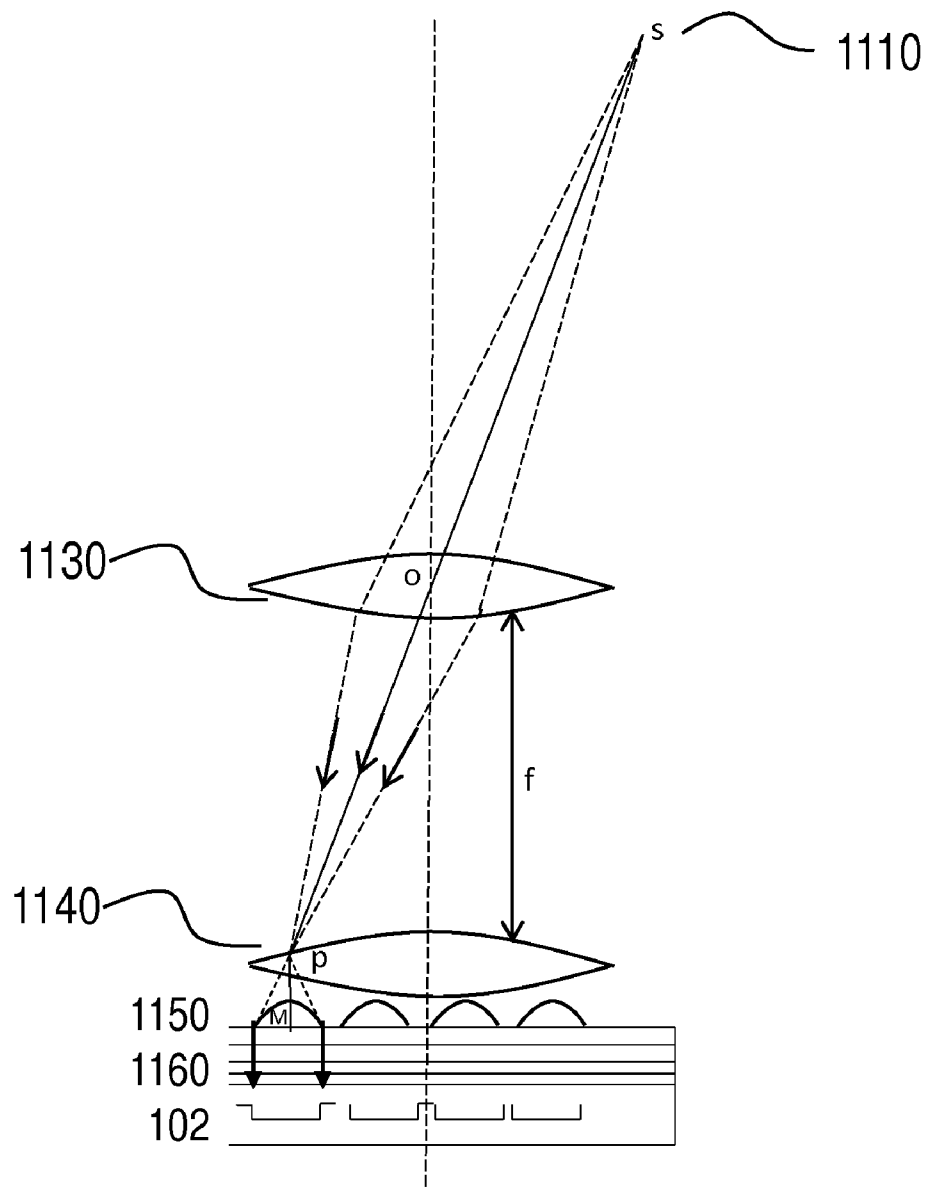


Fig. 12

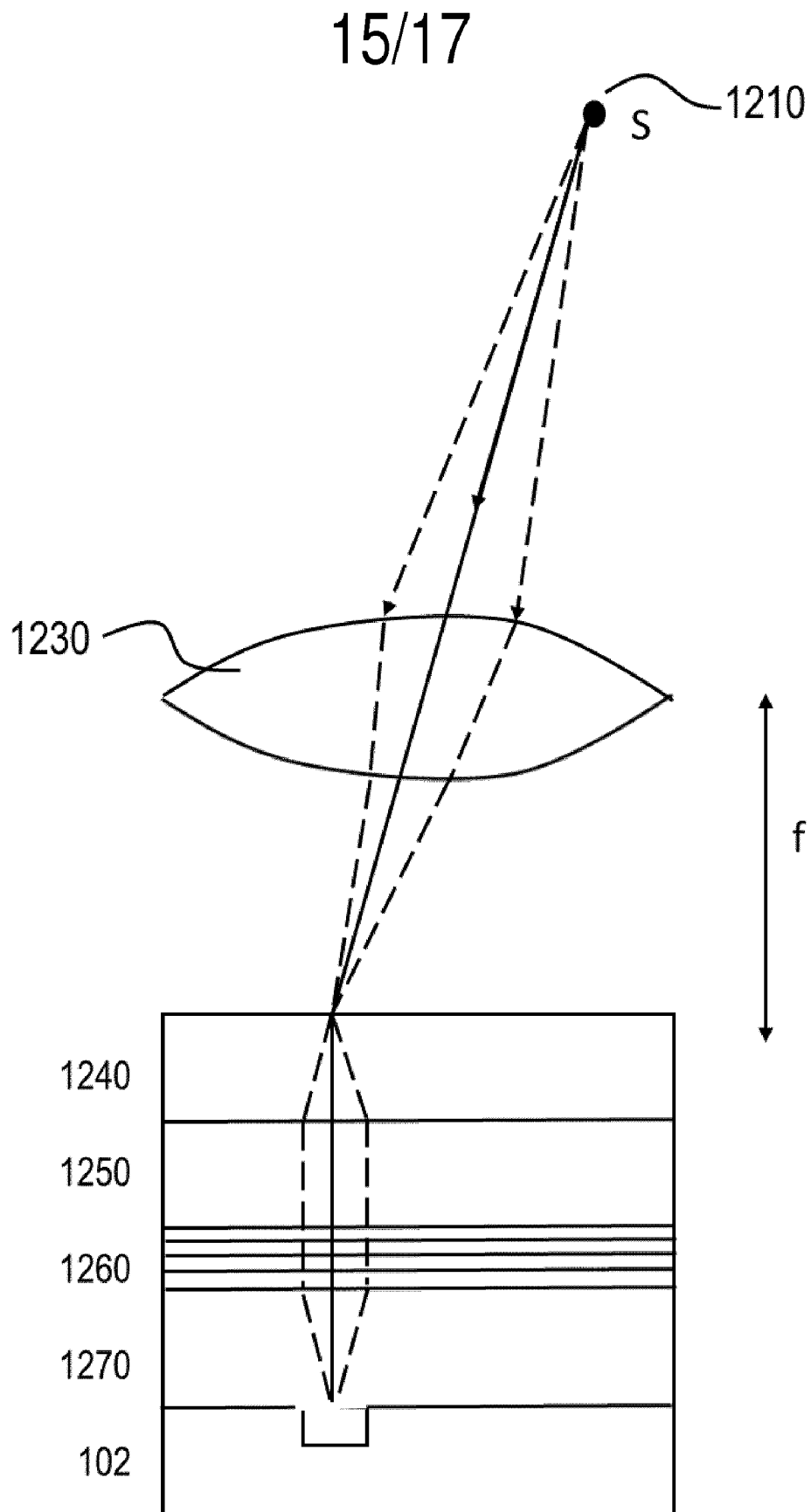


Fig. 13

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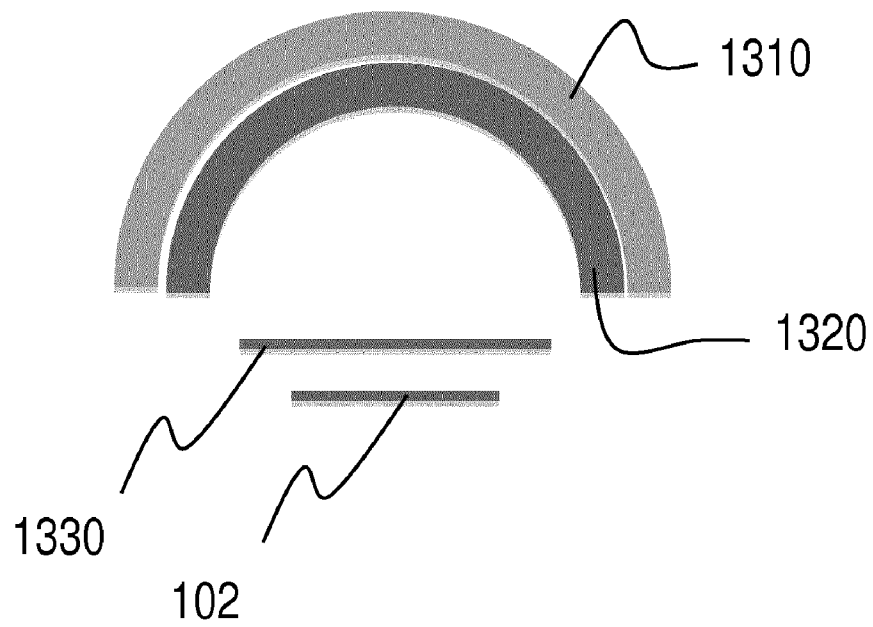


Fig. 14

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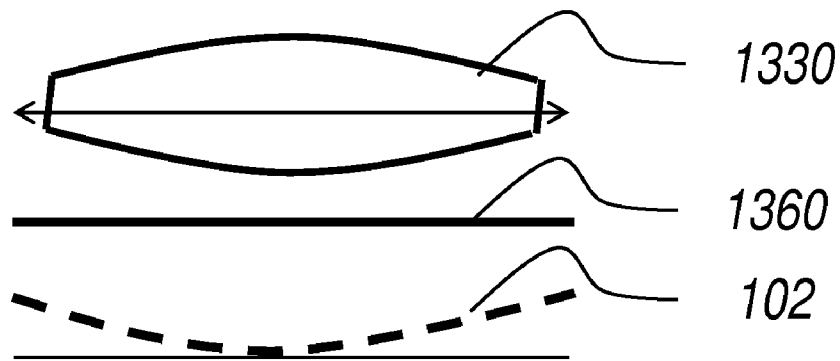


Fig. 15

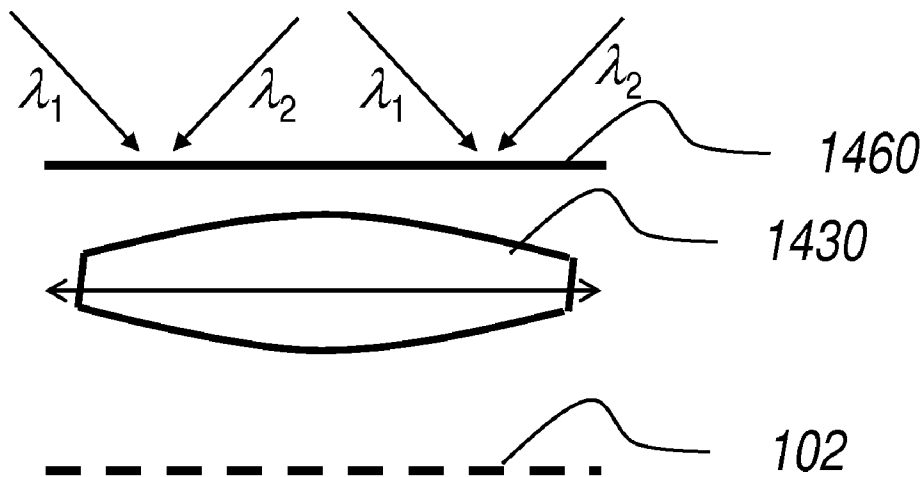


Fig. 16

INTERNATIONAL SEARCH REPORT

International application No
PCT/EP2018/085353

A. CLASSIFICATION OF SUBJECT MATTER
INV. G01S17/10 G01S7/486 G01S7/487
ADD.

According to International Patent Classification (IPC) or to both national classification and IPC

B. FIELDS SEARCHED

Minimum documentation searched (classification system followed by classification symbols)
G01S

Documentation searched other than minimum documentation to the extent that such documents are included in the fields searched

Electronic data base consulted during the international search (name of data base and, where practicable, search terms used)

EPO-Internal, WPI Data

C. DOCUMENTS CONSIDERED TO BE RELEVANT

Category*	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.
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A	----- US 2012/200841 A1 (KAMIYAMA TOMOYUKI [JP] ET AL) 9 August 2012 (2012-08-09) paragraphs [0204] - [0275] figures 21-26	1-18
A,P	----- US 2018/053799 A1 (OTANI MITSUHIKO [JP] ET AL) 22 February 2018 (2018-02-22) paragraphs [0027] - [0148] figures 1-14	1-18
	----- -/-	



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See patent family annex.

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Date of the actual completion of the international search

15 March 2019

Date of mailing of the international search report

01/04/2019

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INTERNATIONAL SEARCH REPORT

International application No

PCT/EP2018/085353

C(Continuation). DOCUMENTS CONSIDERED TO BE RELEVANT		
Category*	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.
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